Raman study of the temperature and magnetic-field dependence of the electronic and lattice properties of MnSi

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The temperature and magnetic-field dependence of lattice and carrier excitations in MnSi is studied in detail using inelastic light scattering. The pure symmetry components of the electronic response are derived from the polarization-dependent spectra. The *E* and *T*² responses agree by and large with longitudinal and optical transport data. However, an anomaly is observed right above the magnetic ordering temperature $T_C = 29$ K that is associated with the fluctuations that drive the transition into the helimagnetic phase first order. The T_1 spectra, reflecting mostly chiral spin excitations, have a temperature dependence similar to that of the E and T_2 symmetries. The response in the fully symmetric *A*¹ representation has a considerably weaker temperature dependence than that in the other symmetries. All nine Raman active phonon lines can be resolved at low temperature. The positions and linewidths of the strongest four lines in E and T_2 symmetry are analyzed in the temperature range $4 < T < 310$ K. Above 50 K, the temperature dependence is found to be conventional and given by anharmonic phonon decay and the lattice expansion. Distinct anomalies are observed in the range of the helimagnetic transition and in the ordered phase. Applying a magnetic field of 4 T, well above the critical field, removes all anomalies and restores a conventional behavior highlighting the relationship between the anomalies and magnetism. The anomaly directly above T_c in the fluctuation range goes along with an anomaly in the thermal expansion. While the lattice constant changes continuously and has only a kink at T_c , all optical phonons soften abruptly, suggesting a direct microscopic coupling between spin order and optical phonons rather than a reaction to magnetostriction effects.

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I. INTRODUCTION

A long-standing problem in the field of itinerant-electron magnetism concerns the interplay of collective excitations such as phonons, plasmons, or magnons with the conduction electrons. While elements such as Fe, Ni, and Co are clearly prototypical for itinerant-electron ferromagnetism and Cr is prototypical for spin-density and charge-density wave order, their relatively high transition temperatures imply large energy scales for the collective excitations that result in a complex interplay. A materials class that has played a major role in the 1970s and 1980s for the development of the present day understanding of itinerant-electron magnetism is weakly magnetic transition-metal compounds such as $ZrZn₂$ or Ni₃Al. For their description, a self-consistent phenomenological model was developed taking into account dispersive spin fluctuations associated with the damping due to the particlehole continuum $[1,2]$. This spin-fluctuation theory is in excellent quantitative agreement with experiment and, during the following decade, became the basis for the description of magnetic quantum phase transitions [\[3,4\]](#page-16-0).

Amongst the weakly magnetic itinerant-electron magnets, the cubic *B*20 compound MnSi has so far probably been studied most extensively. The interest originates thereby in a well-defined hierarchy of energy scales comprising ferromagnetic exchange on the strongest scale, followed by Dzyaloshinsky-Moriya interactions on an intermediate scale and higher-order crystal-electric fields on the weakest scale. Focusing mainly on the highest energy scale, MnSi was studied extensively in the spirit of an essentially ferromagnetic material. These studies motivated in particular a detailed investigation of the suppression of the magnetic transition temperature under hydrostatic pressure, for which a marginal breakdown of the standard model of the metallic state, Fermiliquid theory, was anticipated.

In contrast, while hydrostatic pressure experiments revealed a suppression of magnetic order at $p_c = 14.6$ kbar, the transition was not continuous as expected but rather displayed a first-order character. Despite this lack of (second-order) quantum criticality [\[5\]](#page-16-0), the low-temperature resistivity of MnSi abruptly changes from the T^2 Fermi-liquid dependence for $p < p_c$ to a stable $T^{3/2}$ non-Fermi-liquid (NFL) behavior for $p > p_c$ [\[6\]](#page-16-0). This NFL regime persists over a remarkably wide range in temperature, pressure, and field and is accompanied by partial magnetic order in a small pressure and temperature range on time scales between 10^{-10} s and 10^{-11} s for p_c < $p < p_0 \approx 21$ kbar [\[7,8\]](#page-16-0). Taken together, these findings clearly indicate the importance of the weak spin-orbit interactions in MnSi intimately connecting the NFL behavior to the magnetic structure which indeed is ferromagnetic only on short length scales, i.e., for large momenta.

The extent of this mysterious NFL resistivity appears to be related to the specific form of spin-orbit coupling and magnetic anisotropies mentioned above, which generate a long-wavelength helimagnetic modulation with $\lambda_h \approx 180$ Å along the crystalline $\langle 111 \rangle$ axes. An important consequence of the underlying hierarchy of energies concerns the onset of magnetic order at ambient pressure and $T_{\rm C} \approx 29$ K, which may be described within a Brazovskii scenario [\[9\]](#page-16-0). If $T_{\rm C}$ is approached from the mean-field-disordered paramagnet at high temperatures, isotropic chiral fluctuations evolve on a sphere in reciprocal space with a radius corresponding

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to the helical pitch *λ*h. As the temperature is decreased further, these fluctuations start to interact which gives rise to a fluctuation-disordered regime which inhibits the transition until it becomes first order at T_c [\[10\]](#page-16-0). In a magnetic field, the fluctuations are quenched and the phase transition changes to conventional second order at a field-induced tricritical point [\[11\]](#page-16-0).

Finally, in recent years the largest scientific interest MnSi and its isostructural siblings have attracted was related to the discovery of the skyrmion lattice, i.e., a regular arrangement of topologically nontrivial spin whirls, in a small phase pocket just below T_c [\[12–19\]](#page-16-0). If current is passed through this magnetic texture, the spins of the conduction electrons adiabatically follow the local magnetization, thereby collecting a Berry phase. The latter may be interpreted as an emergent magnetic field of the flux quantum that each skyrmion carries and leads to a topological contribution to the Hall effect [\[20\]](#page-16-0). In combination with the weak collective defect pinning of the skyrmion lattice [\[21\]](#page-16-0), this very efficient coupling allows for spin-transfer torque effects already at ultralow current densities [\[22–24\]](#page-16-0). A careful study of the evolution of the topological Hall effect as a function of pressure suggests an intimate connection of the skyrmion lattice at ambient pressure with the NFL regime at high pressure [\[25,26\]](#page-16-0). While this finding clearly suggests the presence of topologically nontrivial spin textures above p_c , the microscopic origin of the stable $T^{3/2}$ dependence of the resistivity remains puzzling.

In order to unravel the underlying mechanisms that cause the NFL resistivity at high pressures, however, a full account for the conduction at ambient pressure is an important prerequisite. In fact, due to the complex Fermi surface of MnSi, multiple bands are expected to contribute which requires a probe of the electrical conductivity that circumvents the limitations of conventional electric transport measurements and separately accounts for these different contributions.

A further important aspect concerns the coupling of the conduction electrons to the lattice since a change of the lattice constant by less than a percent, caused by either pressure [\[5\]](#page-16-0) or substitutional doping $[27,28]$, is already sufficient to suppress magnetic order and distinctively change the electronic properties. A substantial impact of the conduction electrons on the lattice was also found in ultrasonic attenuation [\[29](#page-16-0)[,30\]](#page-17-0) and thermal expansion measurements, where an influence of magnetism can be detected up to 200 K [\[31–33\]](#page-17-0).

These issues may be addressed via Raman spectroscopy, i.e., inelastic light scattering, for which selection rules allow the separate detection of excitations having different symmetries. An improved optical setup permits us to collect enough inelastically scattered photons to study MnSi at low temperatures and in an external magnetic field. As will be illustrated in the following, the Raman response may be separated: (i) A lattice contribution which is particularly informative here since all optical phonons are Raman active as shown for the isostructural compound FeSi [\[34,35\]](#page-17-0). In particular, also the infrared (IR) active polar phonons can be observed by light scattering due to the missing inversion symmetry in MnSi. The phonons are related to magnetovolume effects via the Grüneisen parameter. Beyond that, they can be used as microscopic probes providing information on possible spin-lattice interactions which may have eluded macroscopic thermodynamic measurements. (ii) A particle-hole continuum, where the pure symmetries correspond to different regions in the Brillouin zone $[36,37]$. The electronic continuum provides access to the anisotropy of fluctuations [\[38–40\]](#page-17-0) and to the **k** dependence of the (two-particle) electronic relaxation rates.

To the best of our knowledge, there is only one Raman study carried out on MnSi prior to our work. Tite *et al.* reported Raman data for elevated temperatures resolving eight out of nine predicted phonons [\[41\]](#page-17-0). IR spectroscopy investigations were performed at low temperatures by Mena *et al.* [\[42\]](#page-17-0). Here, the authors studied the frequency and temperature dependence of the optical conductivity and the effective mass of the charge carriers revealing an optical conductivity below $T_{\rm C}$ that may not be described by the standard Drude formalism but with a phenomenological approach. The scattering rate and the Kramers-Kronig related effective mass thus deviate from Fermi-liquid behavior which is surprising as it contradicts the results of conventional transport experiments. Yet, if the relaxation depends on momentum **k**, as expected for MnSi [\[43\]](#page-17-0), IR spectroscopy yields averages over the entire Fermi surface.

The paper is organized as follows. In Sec. II, we start with a short account for material-specific parameters, the lowtemperature Raman setup, and further experimental details, where we refer to the Appendices for additional information. Results on the phononic and the electronic parts of the Raman spectra are shown in Secs. [III A](#page-3-0) and [III B,](#page-4-0) respectively. The temperature dependence of phonon frequencies and linewidths as well as on the electronic carrier properties will be discussed in Sec. [IV](#page-4-0) before we finally summarize our findings.

II. EXPERIMENTAL METHODS

A. Sample preparation

MnSi crystallizes in the noncentrosymmetric cubic *B*20 (*P*213) structure. Large high-quality single crystals were prepared in an ultrahigh vacuum compatible image furnace [\[28,](#page-16-0)[44\]](#page-17-0). With optimized parameters, the residual resistivity ratio (RRR) of the single crystals grown can be as high as 300. Further details about the preparation and the characterization can be found in Ref. [\[28\]](#page-16-0). The sample used for the Raman experiments had a RRR of approximately 100. An extensive study of the thermal conductivity as measured on samples from the same batch (cf. Fig. [11\)](#page-13-0) will be published elsewhere. At 532.3 nm and room temperature, the complex index of refraction was determined to be $\hat{n} = 3.28 + 2.36 i$. Using \hat{n} , the fraction of the absorbed photons and their polarization inside the sample can be calculated [\[45\]](#page-17-0). Before being mounted in the cryostat, the sample was oriented via Laue diffraction and cleaved.

B. Raman experiment

The Raman spectra were collected with the sample mounted in a bespoke He-flow cryostat permitting studies at temperatures between 1.8 and 330 K. For the measurements, the sample was inserted through a load-lock chamber into the He gas atmosphere of the variable temperature insert. The sample was thereby positioned in the center of a superconducting solenoid providing a magnetic field of up to 8 T.

As a light source, a solid-state laser emitting at 532.3 nm was used. A custom-made objective lens collected the scattered light. The objective lens covered a solid angle of 0.37 sr (numerical aperture $N.A. = 0.34$) and corrected geometrical aberrations introduced by the cryostat windows. Extreme care was taken to control any extrinsic background. Thus, the scattered light had to be spatially filtered. At the CCD detector, approximately 1 count $(s mW)^{-1}$ arrived in the maximum of the strongest phonon peak and less than 0.1 counts $(s mW)^{-1}$ in the electronic continuum as can be seen in the spectra shown in Fig. [1.](#page-3-0) For one spectrum, six individual exposures of 300 s each were added. This integration time was a tradeoff between the probability of cosmic spikes and the readout noise of the

detector. For a total exposure of 1800 s and an absorbed laser power $P_{\text{abs}} = 4$ mW, approximately 200 photoelectrons per point were collected in the electronic continuum of the spectra corresponding to a statistical error of 7%. Further details are described in the Appendices.

C. Temperature determination

The physical properties observed in the light scattering experiment corresponded to the temperature in the illuminated spot T_s which, due to local heating by the absorbed laser light, was higher than the temperature *T*^h of the sample holder by $\Delta T(T_h)$. In MnSi, the standard methods to determine the laser heating fail due to the low scattering intensity and the lack of strongly temperature-dependent features in the spectra throughout the whole temperature range. To circumvent this problem, the laser heating was determined using a method that was developed for V_3Si [\[46\]](#page-17-0) and then applied to Nb_3Sn [\[47\]](#page-17-0). The application to other (cubic) materials is possible since the transmission coefficient for light $T = 1 - R$ and the thermal conductivity $\lambda(T)$ are the only parameters relevant for the determination of $\Delta T(T_h)$. For more details, see Appendix **B**. At the selected temperatures of the sample holder $T_h = 2$, 30, and 300K, ΔT is 2.9, 1.3, and 0.4K, respectively, for an absorbed laser power $P_{\text{abs}} = 4 \text{mW}$. All measurements shown below are corrected for the laser heating. To simplify the notation, the temperature in the laser spot T_s is referred to as *T* in the following.

D. Response and selection rules

Raman active excitations have spectral and symmetry properties. The measured spectra are proportional to the van Hove function $S_{i,s}(\mathbf{q} \approx 0,\omega)$ with i and s indicating the polarizations of the incoming and scattered photons, respectively. Upon division by the thermal Bose factor ${1 + n(\omega, T)} = (1 - e^{-\hbar\omega/k_BT})^{-1}$ the Raman response $R\chi''_{1, s}$ is obtained, where R is a constant that absorbs experimental factors and takes care of the units.

The light polarizations $\hat{e}_{i,s}$ are the key to access the symmetry properties of the excitations. The symmetry provides information on, e.g., phonon eigenvectors, collective modes, or spin excitations and allow selective access to electron momenta in the Brillouin zone in the case of electron-hole excitations [$36,37$]. \hat{e}_i and \hat{e}_s are set outside the cryostat such that the light polarization inside the sample is aligned with respect to the crystalline axes (cf. Appendix [A\)](#page-12-0). *x* and *y* denote linear polarizations along the crystallographic [100] and [010] axes, respectively. x' and y' are rotated by $45°$ and point along [110] and [110], respectively. Left and right circularly ¯ polarized photons are represented as*l* and *r*. The measurement configuration is given in Porto notation $(\hat{e}_i \hat{e}_s)$. In all cases, a linear combination of symmetries is projected out.

In the space group of MnSi only the three irreducible representations A, E, and T exist implying that, e.g., $x'y'$ + $xy - rl \equiv 0$. This holds true only for the phonons (cf. Ref. [35]) but not for the continua having a strong antisymmetric component $x'y' + xy - rl = 2T_1$ [see Fig. 2(a)]. A distinction between the symmetric T_2 and antisymmetric T_1 contributions is only possible in the next higher space group *O* with the replacements $A \to A_1$, $E \to E$, and $T \to T_2$ (for further details see Appendix [E\)](#page-15-0). In *O* the main polarizations yield

$$
xx = A_1 + \frac{4}{3} E, \qquad xy = T_1 + T_2,
$$

\n
$$
x'x' = A_1 + \frac{1}{3} E + T_2, \qquad x'y' = E + T_1,
$$

\n
$$
rr = A_1 + \frac{1}{3} E + T_1, \qquad rl = E + T_2.
$$

\n(1)

Factor group analysis predicts nine Raman active phonons in MnSi $(2A_1 + 2E + 5T_2)$ [\[35\]](#page-17-0). The response of a symmetry μ can be determined via linear combinations of measured spectra

$$
A_1 = \frac{1}{3}[(xx + x'x' + rr) - (x'y' + rl)],
$$

\n
$$
E = \frac{1}{3}[(xx + x'y' + rl) - \frac{1}{2}(xy + x'x' + rr)],
$$

\n
$$
T_1 = \frac{1}{3}[(xy + x'y' + rr) - \frac{1}{2}(xx + x'x' + rl)],
$$

\n
$$
T_2 = \frac{1}{3}[(xy + x'x' + rl) - \frac{1}{2}(xx + x'y' + rr)].
$$
\n(2)

If the two spectra of each line in Eq. (1) are added, the entire response is obtained. The three sums should return exactly the same results and can be used to check the consistency of the measurements as shown, e.g., in Fig. $2(b)$. This consistency check was performed at 17, 36, 288 and 311 K. At other temperatures only xy , $x'y'$, rr , and rl spectra were measured. Four spectra are still sufficient to calculate the pure symmetries, e.g., $E = (x'y' + rl - xy)/2$, but are not enough for the full consistency check. In magnetic field, only the circular polarizations were measured because they are not affected by polarization rotations due to the Faraday effect.

III. RESULTS

We studied electronic and lattice excitations of MnSi in the temperature range $1.8 < T_h < 310$ K as a function of the light polarizations. The main emphasis was placed on the temperature range below 50 K close to the helimagnetic transition at $T_C = 29$ K. In some measurements, a magnetic field of 4 T was applied to suppress the helimagnetic modulation.

In Fig. [1,](#page-3-0) Raman spectra $R\chi''_{i,s}$ at 288 and 17K are shown. The results for the various polarization combinations are offset by 0.7 counts $(s \text{ mW})^{-1}$ each. Along with the measurements, the linear combination of symmetry components contributing to the spectra is indicated. All spectra consist of sharp peaks, originating from lattice excitations, and a very weak continuum arising from electron-hole or other excitations having a broad spectrum.

The pure symmetry components can be derived from the experimental spectra (Fig. [1\)](#page-3-0) via the linear combinations compiled in Eq. (2) and are shown in Fig. $2(a)$ for low temperatures. Figure $2(b)$ demonstrates that the six spectra shown in Fig. $1(b)$ are consistent. This holds for both the phonons and the continuum.

FIG. 1. (Color online) Raman spectra of MnSi at (a) 288 and (b) 17 K. Plotted is the Raman susceptibility $R\chi^{\prime\prime}_{i,s}(\omega,T)$ as a function of the energy shift *ω*. The spectra are measured with different sets of light polarizations with respect to the crystallographic axes as explained in the text. For each polarization combination, the symmetry components are indicated. For clarity, the spectra are consecutively offset vertically by 0.7 counts $(s mW)^{-1}$. To point out the small frequency differences between E and T_2 phonons, the positions of the two *E* phonons in the *xx* spectra are marked by dashed lines. Whenever both E and T_2 excitations contribute to a spectrum, double-peak structures appear. Upon lowering the temperature, all phonons harden. The black horizontal arrows indicate these frequency shifts for the *E* phonons.

A. Phonons

In the raw data in Fig. 1, not all phonons are immediately observable since some of them are rather close in energy. However, the temperature dependence of the four strongest lines can be read directly from the data: two in *E* (marked by dashed lines) and two in T_2 symmetry. The energies of the two strong T_2 lines are only slightly different from those of the *E* phonons. Therefore, the *E* and T_2 modes in the $x'x'$ and *rl* spectra appear as double-peak structures. However, they can be observed independently in the $x'y'$ and xy spectra, respectively. There are also three weak T_2 and two weak A_1 phonon lines. These low-intensity phonons are hardly visible

FIG. 2. (Color online) Symmetry-resolved spectra of MnSi at 17 K. (a) Pure symmetries can be obtained via linear combinations of Raman spectra measured with different polarization settings according to Eq. [\(2\)](#page-2-0). For clarity, the spectra are offset by 0.35 counts (s mW)⁻¹. All Raman active phonons (2*E* + 5*T*₂ + 2*A*) predicted by factor group analysis [\[35\]](#page-17-0) are observed (marked by arrows). In the A_1 and T_1 spectra, there are additional peaks due to polarization leakage (marked by stars). The inset shows the weaker phonons of T_2 and *A*¹ symmetry on an expanded intensity scale (spectra offset by 0.1 counts $(s \, mW)^{-1}$). The T_1 spectrum contains the chiral excitations. It is featureless except for polarization leakage (stars), but the intensity of the continuum is in the same order of magnitude as the other symmetries. (b) Sums of spectra having orthogonal polarizations of the scattered photons. Two orthogonal measurements cover the full response of the sample, thus their sums must be invariant. This is used to check the consistency of the measurements.

on the scale of Fig. 1, but are nonetheless marked in Fig. 2. As expected, no phonons are present in T_1 symmetry.

In Table [I,](#page-4-0) we show the frequencies of the phonons measured at 17 and 288 K along with the results of Tite *et al.*[\[41\]](#page-17-0). At room temperature, only eight of the nine expected phonons can be detected while all are seen at low temperature. The missing T_2 line turns out to be very weak and appears only as a shoulder at 332 cm^{-1} on the high-energy side of the line at 318.6 cm[−]1. A comparison with the phonon positions in the isostructural compound FeSi [\[35\]](#page-17-0) supports this finding.

TABLE I. Energies of the Raman active phonon modes in MnSi. At low temperatures, all nine predicted peaks are resolved. Roomtemperature measurements are shown together with the phonon positions derived in Ref. [\[41\]](#page-17-0). The frequency values of the four intense phonons can be determined with an accuracy of about ±0*.*2cm[−]¹ using Voigt fits (boldface). The other phonons are determined with a precision of $\omega_{ph} \pm 1$ cm⁻¹.

	Phonon frequency ω_{ph} (cm ⁻¹)			
	$T \approx 295 \text{ K}$ (Ref. [41])	$T = 288 \text{ K}$ (This work)	$T = 17K$ (This work)	
A ₁	268	268	271	
A ₁	398	396	402	
E	193	193.5	196.9	
E	319	318.5	323.4	
T ₂	194	196.3	200.9	
T_2	236	239	244	
T_2	316	313.9	318.6	
T_2			332	
T_2	448	447	452	

Tite and co-workers [\[41\]](#page-17-0) performed their measurements at elevated temperatures using various high-laser powers. Considering their laser power P_{abs} and their focus size r_0 in Eq. [\(B2\)](#page-14-0), the associated temperatures may be estimated to be as high as 650 K. The huge heating ΔT implies an inhomogeneous broadening of the phonon lines explaining the different linewidths reported in Ref. [\[41\]](#page-17-0) and in our study. On the other hand, if the temperature dependence of the phonon energies $\omega_{ph}(T)$ is assumed to be linear above room temperature, Tite *et al.* are able to extrapolate the phonon positions down to 295 K in satisfactory agreement with our data (cf. Table I).

In our study, the temperature range was extended down to 4 K. Particular emphasis was placed on the temperature range around the helimagnetic phase transition at 29 K. With decreasing temperature, all phonons shift to higher energies. At the transition, this trend is reversed, and the phonons soften by typically half a percent. To verify these small shifts in the phonon frequencies, the stability of the experimental setup was rechecked before and after each measurement with the spectral lines of a neon calibration lamp. Fitting Voigt profiles to the phonon lines allowed us to reproducibly determine the frequencies and widths with an accuracy of approximately ±0*.*2 cm[−]1. A Voigt fit consists of a convolution of a Lorentzian and a Gaussian profile. The Gaussian width was fixed at 2 cm^{-1} and represents the spectral resolution. The width, position, and spectral weight of the Lorentzians were the fitting parameters. In this way, better results could be obtained than with pure Lorentzian line shapes since the phonons are rather narrow, and the spectral resolution can not be reduced any further for intensity reasons. The position of the phonon lines was determined from raw data rather than from pure symmetry spectra to avoid artifacts arising from linear combinations of the spectra (cf. Fig. [2\)](#page-3-0). Also, the E and T_2 phonons that are very close in frequency can be separated by using $x'y'$ and xy measurements [cf. Eq. [\(1\)](#page-2-0)]. The results for the temperature dependence of the position and linewidth of these phonons are shown in Figs. [4](#page-5-0) and [5](#page-6-0) in Sec. [IV A](#page-5-0) and will be discussed there in detail.

The *xy* spectrum projects both *T* symmetries. In *T*¹ symmetry, neither phonons nor conduction electrons appear, but only excitations where the chiral symmetry changes. These excitations include transitions between states with well-defined orbital character such as crystal-field excitations $[48]$. As shown in Fig. $2(a)$, displaying the pure symmetries, the response does not vanish, indicating the presence of excitations beyond scattering from phonons and electron-hole pairs that will be addressed in Secs. III B and [IV B.](#page-8-0) In addition, the inset of Fig. $2(a)$ demonstrates that the T_1 continuum is too strong to be neglected. Therefore, if the continua of the other symmetries are to be analyzed, only the pure symmetries [Fig. $2(a)$] can be used. Prior to an analysis of the continuum, it is necessary to subtract the phonons. To this end, we apply the fitting procedure described above to all phonons, subtract them, and thereby obtain the isolated continuum.

B. Continuum

The electronic continua observed in the pure symmetries are plotted in Fig. [3](#page-5-0) for various temperatures in the range $13 \leq T \leq 288$ K. The continua were obtained by subtracting the individually fitted phonons from the spectra. Although the fits were reproducible and stable, there are occasionally remainders of phonons after the subtraction, particularly in the low-temperature spectra having phonon linewidths similar to the spectral resolution. The data are relatively noisy in general since the scattering cross sections are low (see Sec. \overline{I} IB) and the spectra in pure symmetries are the result of subtraction procedures [cf. Eq. [\(2\)](#page-2-0)].

In all symmetries, the spectra exhibit a substantial temperature dependence at low energies. The E , T_1 , and T_2 spectra are also temperature dependent at higher energies. At 13 K, the *A*1, *E*, and T_1 spectra are too steep below 50 cm⁻¹ to allow the extrapolation to zero at $\omega \to 0$ to be observed. In fact, $\chi''(-\omega) =$ $-\chi''(\omega)$ is expected since, for causality reasons, the response is antisymmetric. Only the T_2 spectra show the expected linear energy dependence at all temperatures and extrapolate approximately to zero. The variation with temperature implies a substantial increase of the initial slope of the response.

As discussed in detail by Opel and co-workers [\[49\]](#page-17-0), the inverse initial slope $\left[\frac{\partial \chi''(\omega)}{\partial \omega}\right]^{-1}$ corresponds to a Raman resistivity and is therefore a useful quantity to be compared with transport measurements. It can be extracted in a similar fashion as conductivity from the optical spectra (IR) if a wider energy range is known. In the case of the Raman spectra, the requirements as to the known spectral range are much more relaxed than in optical spectroscopy since the Kramers-Kronig transform converges rapidly [\[49\]](#page-17-0). The results of this analysis, in particular those in the zero-energy limit, will be shown and discussed in Sec. [IV B](#page-8-0) (Figs. [7](#page-10-0)[–9\)](#page-11-0).

IV. DISCUSSION

Major anomalies of the lattice and the carrier properties are observed close to T_C while the high-temperature range develops more conventionally. First, we discuss the phonons, then the electronic response. In each case, we start with the behavior above the helimagnetic transition at T_c followed by a detailed study close to $T_{\rm C}$.

FIG. 3. (Color online) Temperature and symmetry dependence of the electronic continua in all pure symmetries $\mu = A_1, E, T_1, T_2$. The response is obtained via linear combinations of xy , $x'y'$, rr , and *rl* spectra. Phonons were fitted with Voigt profiles and subtracted.

A. Temperature dependence of the phonons

Figures 4 and [5](#page-6-0) show the temperature dependencies of the frequencies and linewidths of the two strongest T_2 and *E* phonons as derived from Voigt fits (cf. Sec. [III A\)](#page-3-0). As temperature decreases in the range $T > 35$ K, there is the typical blue-shift and line narrowing. Right above $T_{\rm C}$, in the range between 35 and 29 K, there is a dip in all phonon frequencies. Below the transition, the phonons anomalously soften by approximately 0.5 cm^{-1} as can be seen more clearly in panels (c) and (d) of Figs. 4 and 5 . Except for the high-energy T_2 mode, all lines harden again below approximately $1/2 T_C$. The T_2 mode at 201 cm⁻¹ [Fig. [5\(d\)\]](#page-6-0) reaches the same energy as found at T_c ,

FIG. 4. (Color online) Temperature dependence of the *E* phonons. Shown are the frequencies (left scale) and linewidths (right scale) of the two strongest lines with representative error bars (labeled by $E^{(318)}$ and $E^{(194)}$ according to their room-temperature positions). (a) and (b) show the analysis for the full temperature range, (c) and (d) zoom in on low temperatures. For both phonons, $E^{(318)}$ and $E^{(194)}$, the linewidth can be described by the model of anharmonic decay [\[51\]](#page-17-0) (black lines). The main contribution to the frequency change is due to thermal expansion and can be described by a constant Grüneisen parameter $\gamma_i = 2.5$ above 35 K (orange line). Right above T_c (dashed vertical line) in the fluctuation disordered regime [\[11\]](#page-16-0) (shaded) there is a dip in the phonon frequency. If the helical order is suppressed by a magnetic field of 4 T (triangles and circles), the anomalies in the phonon frequencies disappear.

whereas the *E* lines (Fig. 4) even exceed the low-temperature extrapolation value expected from the range $T > T_C$.

All anomalies of the phonon energies vanish completely in a magnetic field of 4 T (see Fig. 4), which is well above 0*.*6T, the upper critical field of the helimagnetic modulation. Nevertheless, a crossover temperature T_{cr} continues to exist that separates the regimes dominated by either magnetism or temperature. For MnSi at $B = 4T$, T_{cr} is approximately 40 K [\[50\]](#page-17-0). However, no anomalies in the phonon positions and widths are detected at this temperature, suggesting that the phonon anomalies originate from the chiral order.

FIG. 5. (Color online) Temperature dependence of T_2 phonons. Shown are the frequencies (left scale) and linewidths (right scale) of the two strongest lines (labeled by $T_2^{(314)}$ and $T_2^{(197)}$ according to their room-temperature positions). (a) and (b) show data for the full temperature range, (c) and (d) zoom in on low temperatures. The phonon width deviates from the predictions of the Klemens model [\[51\]](#page-17-0) (black lines) only for the $T_2^{(197)}$ phonon below T_C (dashed vertical line). Above 35 K, the frequency change of both phonons can be explained in terms of a thermal expansion shift $\Delta_i^{(1)}(T)$ (orange lines) assuming a constant $\gamma_i = 2.5$ for all phonon modes *i*. There is a dip in the phonon frequency right above T_C in the fluctuation-disordered region $[10,11]$ (shaded). The dip can be reproduced qualitatively if the macroscopic Grüneisen parameter $\gamma_{\text{macro}}(T)$ is inserted into Eq. [\(9\)](#page-7-0) as described in the text (dashed magenta line). In the helimagnetic phase the phonon frequencies are lower than those predicted by the thermal expansion.

We first focus on the high-temperature part. In the harmonic approximation of lattice dynamics, the phonon frequencies are not temperature dependent, and the phonon lifetime is infinite. In real systems and to describe the experimentally observed temperature dependencies of frequency and lifetime, anharmonic contributions to the lattice potential have to be taken into account. A consequence of these anharmonic terms are collisions between phonons which lead to changes in the phonon frequency and to the creation or annihilation of phonons resulting in a finite lifetime. Frequency shift and broadening can be described in terms of the real and imaginary parts of the self-energy [\[52\]](#page-17-0)

$$
\Sigma_i(T) = \Delta_i(T) + \iota \Gamma_i(T) \tag{3}
$$

corresponding to the position and width of phonon *i*, respectively. The anharmonic effects can be treated perturbationally and were extensively studied by several authors [\[51–54\]](#page-17-0).

Here, we consider only optical phonons in the center of the Brillouin zone. Taking into account energy and momentum conservation, an optical phonon with $q = 0$ decays into two acoustic phonons of opposite wave vectors $\omega_1(\mathbf{q}, j_1) + \omega_2(-\mathbf{q}, j_2) = \omega_{\text{ph}}$. The indices j_1 and j_2 label acoustic phonon dispersion branches. Klemens assumes [\[51\]](#page-17-0) that the most relevant decay channels are symmetric, $\omega_1(\mathbf{q}, j_1) = \omega_2(-\mathbf{q}, j_1) = \omega_{ph}/2$, and within the same acoustic phonon branch, e.g., *j*1. Then, the temperature dependence of the linewidth of phonons reads as

$$
\Gamma_{\text{ph},i}(T) = \Gamma_i(0) \left[1 + \frac{2\lambda_{p-p,i}}{\exp\left(\frac{\hbar\omega_i(0)}{2k_{\text{B}}T}\right) - 1} \right].
$$
 (4)

The width $\Gamma_i(0)$ and position $\omega_i(0)$ of the *i*th Raman line for $T \to 0$ can be obtained by extrapolating $\Gamma_{ph, i}(T)$ to zero temperature from the range above T_C before the anomalies set in. As temperature rises, the linewidth increases by two times the Bose factor at $\omega_i(0)/2$, representing the symmetric decay channel. $\lambda_{p-p,i}$ was introduced as the only fitting parameter and is interpreted as phonon-phonon coupling strength. More general calculations including asymmetric decay channels result in a better agreement with experiment in some semiconductors [\[52,55\]](#page-17-0). In MnSi, however, asymmetric phonon decays as well as four phonon processes turn out to be negligible, and the Klemens model provides a reasonable fit to the linewidth of all phonons studied, except $T_2^{(197)}$ at low temperatures.

The frequency shift of the peaks is described by the real part of the self-energy $\Delta_i(T)$ in Eq. (3). The temperature dependence of phonon *i* reads as

$$
\omega_{\text{ph},i}(T) = \omega_i(0) + \Delta_i(T). \tag{5}
$$

Here, only the two lowest-order contributions $\Delta_i(T) =$ $\Delta_i^{(1)}(T) + \Delta_i^{(2)}(T)$ will be discussed. A detailed description may be found in Refs. [\[52,55\]](#page-17-0). The leading term $\Delta_i^{(1)}(T)$ originates from the thermal lattice expansion, hence is related to a macroscopic quantity. Before we derive $\Delta_i^{(1)}(T)$, we show that $\Delta_i^{(2)}(T)$ is small for the phonon energies and the temperature range studied here.

The second-order contribution $\Delta_i^{(2)}(T)$ results from the anharmonic decay of phonons. The approximate relationship between the eigenfrequency $\omega_i(0)$, the resonance frequency $\omega_{ph,i}$ (peak maximum), and the linewidth Γ_i (FWHM) $\omega_{ph,i}$ = $\sqrt{\omega_i(0)^2 - \Gamma_i^2}$ of a damped harmonic oscillator along with Eq. (4) yield a shift

$$
\Delta_i^{(2)}(T) = -C_i \left[1 + \frac{4\lambda_{p-p,i}}{\exp \frac{\hbar \omega_0}{2k_B T} - 1} \right],
$$
 (6)

with $C_i = \Gamma_i(0)^2/2\omega_i(0)$ and all other parameters as defined above. The parameters for the phonons analyzed here are

TABLE II. Phonon parameters. According to their symmetry and room-temperature frequency, the phonons *i* are labeled $E^{(194)}$, $E^{(318)}$, $T_2^{(197)}$, and $T_2^{(314)}$. $\omega_i(0)$, $\Gamma_i(0)$ are experimentally determined constants. The phonon-phonon coupling strength $\lambda_{p-p,i}$ results from the fit of the phonon width according to Eq. [\(4\)](#page-6-0) and was used again in Eq. [\(6\)](#page-6-0).

Fit parameter					
	F(194)	F(318)	$T_2^{(197)}$	$T_2^{(314)}$	
$\omega_i(0)$ (cm ⁻¹)	197.5	324.1	201.2	319.2	
$\Gamma_i(0)$ (cm ⁻¹)	2.3	3.5	4.4	7.2	
$C_i = \Gamma_i(0)^2/2\omega_i(0)$ (cm ⁻¹)	0.013	0.019	0.048	0.081	
$\lambda_{p-p,i}$	0.15	0.2	0.07	0.14	

compiled in Table II. The additional factor 2 in the numerator compared to Eq. [\(4\)](#page-6-0) is due to the damped harmonic oscillator approximation. For the phonon-phonon coupling $\lambda_{p-p,i}$, the values obtained from Eq. [\(4\)](#page-6-0) are used again. It turns out that the coupling is stronger for E than for T_2 phonons and also stronger for the high-frequency modes.

As $\Gamma_i(0)$ is small in comparison to $\omega_i(0)$, the coefficient C_i is small and the contribution of $\Delta_i^{(2)}$ to the phonon shift is at least two orders of magnitude smaller than the thermal expansion shift $\Delta_i^{(1)}$ and therefore negligible. $\Delta_i^{(2)}$ gives significant contributions only for phonons with very low frequencies or temperatures in excess of the Debye temperature Debye being as high as 600K here [\[54,56,57\]](#page-17-0). Obviously, the dominating contributions to the widths and the frequency shifts of the phonons result from different mechanisms and thus are not directly interrelated. This explains why the anomalies in the phonon frequencies do not have a direct correspondence in the linewidths.

The first-order term $\Delta_i^{(1)}$ depends on the unit-cell volume. In general, the resonance frequencies of the phonons increase upon decreasing the unit-cell volume since the forces between the atoms increase with decreasing distance. The change can be quantified via the microscopic Grüneisen parameter γ_i [\[58\]](#page-17-0) of mode *i* being defined as the negative logarithmic derivative of a normal-mode frequency ω_i with respect to the volume *V*:

$$
\gamma_i = -\partial(\ln \omega_i)/\partial(\ln V). \tag{7}
$$

The related thermodynamic quantity is the macroscopic Grüneisen parameter $\gamma_{\text{macro}}(T)$ which is a weighted average of the contributions from the lattice, as well as from charges and magnetism [\[59\]](#page-17-0). For the phonon part it can be shown that the relative weight is given by their individual contributions to the specific heat [\[58\]](#page-17-0). While $\gamma_{\text{macro}}(T)$ is approximately constant in conventional insulators, it may vary considerably with temperature in complex metallic systems whenever different contributions determine the thermodynamic proper-ties [\[59,60\]](#page-17-0). $\gamma_{\text{macro}}(T)$ can be determined from experimentally accessible thermodynamic properties alone [\[60\]](#page-17-0):

$$
\gamma_{\text{macro}}(T) = \frac{3\alpha(T)K(T)V^{\text{mol}}(T)}{C_p^{\text{pol}}(T)}
$$
(8)

and can directly be calculated up to 100 K using the published data of the coefficient of thermal expansion $\alpha(T)$, the bulk modulus $K(T)$, the molar volume $V^{\text{mol}}(T)$, and the molar heat capacity $C_p^{\text{mol}}(T)$ [\[11](#page-16-0)[,30,33,61\]](#page-17-0). Each of the quantities

contributing to γ_{macro} is temperature dependent with strong anomalies close to $T_{\rm C}$. Consequently, also $\gamma_{\rm macro}$ depends on temperature as shown in Fig. [14](#page-15-0) in the Appendix. For $T \to 0$, $\gamma_{\text{macro}}(T)$ is expected to asymptotically approach zero as α vanishes. Upon approaching T_c from low temperatures, Eq. (8) yields large negative values of approximately -15 . Slightly above the transition there is a pronounced dip-hump structure with the minimum at 30 K, the maximum at 35 K, and a sign change in-between. Upon further increasing the temperature, $\gamma_{\text{macro}}(T)$ asymptotically approaches the constant value of 2.5 from above. Therefore, *γ*_{macro} was set to 2.5 above 100 K because not all quantities entering Eq. (8) were available up to room temperature.

In MnSi magnetostrictive effects contribute to the anomalies of $\gamma_{\text{macro}}(T)$ around T_{C} , and relatively large values even at elevated temperatures are to be expected. For instance, the magnetic contributions to $\alpha(T)$ play an important role up to at least 200 K and are of the same order of magnitude as the nonmagnetic ones [\[32\]](#page-17-0). At low temperatures, magnetic order drives $\alpha(T)$ even negative, i.e., the lattice expands upon cooling, and leads to the strong dip of $\gamma_{\text{macro}}(T)$ around *T*^C [\[30,32,33\]](#page-17-0).

It is not the purpose of this study to systematically disentangle the various contributions to $\gamma_{\text{macro}}(T)$ or to determine their respective weight. Rather, we wish to find out to which extent $\Delta_i^{(1)}(T)$ can be understood in terms of bulk properties and where microscopic effects can be pinned down. We first calculate $\Delta_i^{(1)}(T)$ using Eq. (7). For constant γ_i , Eq. (7) can be integrated [\[53\]](#page-17-0) yielding an expression for the frequency shift $\Delta_i^{(1)}(T)$ of phonon *i*:

$$
\Delta_i^{(1)}(T) = \omega_i(0) \left\{ \exp \left[-3\gamma_i \int_0^T \alpha(T') dT' \right] - 1 \right\}.
$$
 (9)

The phonon frequency $\omega_i(0)$ is the only free parameter which can be determined for each branch *i* by a fit to the hightemperature data. The temperature dependencies of $\omega_{ph,i}(T)$ according to Eq. (9) are plotted as orange lines in Figs. [4](#page-5-0) and [5.](#page-6-0) At temperatures above 100 K, the frequency changes of the Raman phonons are well described by $\Delta_i^{(1)}(T)$ with a constant Gruneisen parameter $\gamma_i = 2.5$ in good agreement with the asymptotic limit of $\gamma_{\text{macro}}(T)$. Approaching the phase transition from above, the phonon frequencies may increase slightly as does $\gamma_{\text{macro}}(T)$ (see also Fig. [14\)](#page-15-0). Similarly, the experimentally observed dip at $30 K > T_C$ has a corresponding anomaly in $\gamma_{\text{macro}}(T)$. At T_{C} all phonon frequencies jump back to the value at $T > 30$ K and then soften again. The phonon anomaly at $T_{\rm C}$ is unparalleled in any of the macroscopic quantities. While the $T_2^{(314)}$ phonon seems to stay at lower frequency, the other phonons reach frequencies above $\omega_i(0)$. The prediction according to Eq. (9) shows only a tiny kink which originates from $\alpha(T)$ [since all other quantities in Eq. (9) are constant]. For $T \to 0$, $\Delta_i^{(1)}(T)$ vanishes as $\int \alpha \, dT'$ in the exponent goes to zero.

To summarize this part, we find that the widths of the four strongest phonons can be well understood in terms of symmetric anharmonic decay in the entire temperature range studied. The phonon energies are compatible with the thermodynamic properties in the temperature range above 50–100 K. More specifically, constant and mode-independent

Grüneisen parameters γ_i which, additionally, coincide here with *γ*_{macro} are sufficient. Below 50–70 K, *γ*_{macro} increases towards a maximum at 35 K (see Fig. [14\)](#page-15-0). A similar maximum may be present for the $T_2^{(197)}$ phonon [Fig. [5\(d\)\]](#page-6-0). As to the other three lines, the experimental accuracy is insufficient to resolve deviations from the simple expectation on the basis of constant γ_i parameters. While the anomaly at 30 K right above $T_{\rm C}$ is still clearly visible in the temperature dependence of both *γ*macro and the phonon frequencies, we find phonon anomalies without a corresponding anomaly in the bulk right at $T_{\rm C}$ in contrast to what is found in insulating magnets [\[62–64\]](#page-17-0). The results with applied field demonstrate that there are no phonon anomalies without short- or long-ranged chiral order.

In order to disentangle thermodynamic and microscopic properties we insert γ_{macro} in Eq. [\(9\)](#page-7-0) and recalculate $\Delta_i^{(1)}(T)$. This is motivated by the proximity of the anomalies in the phonon energies $\omega_{ph,i}(T)$ and of $\gamma_{macro}(T)$ but can not be justified mathematically since Eq. [\(7\)](#page-7-0) yields Eq. [\(9\)](#page-7-0) only for a constant γ_i . As shown in Fig. [5,](#page-6-0) the shift obtained in this way (dashed magenta lines) is identical to that for $\gamma_i = 2.5$ (orange lines) down to approximately 50 K but deviates below. The anomaly of $\omega_{ph,i}(T)$ observed right above T_c has now a correspondence in the prediction, while that at T_C can not be reproduced. Similar results are found for *E* symmetry but are not plotted to avoid overloading Fig. [4.](#page-5-0)

The interrelation of microscopic and thermodynamic properties can be visualized in a better way by looking at the difference between the experimental frequencies $\omega_{ph,i}(T)$ and those calculated on the basis of Eq. [\(9\)](#page-7-0) using $\gamma_{\text{macro}}(T)$. Figure 6 demonstrates that the anomaly above $T_{\rm C}$ vanishes almost completely (with small phonon-specific variations) while that at $T_{\rm C}$ is rather pronounced. Although the use of $\gamma_{\rm macro}(T)$ in Eq. [\(9\)](#page-7-0) is sloppy, it is safe to conclude that the anomaly in the fluctuation-disordered regime has a correspondence in the macroscopic properties while that at T_C is of microscopic origin. In this way, the temperature dependence indicates that the phonons and $\gamma_{\text{macro}}(T)$ react differently to the formation of helimagnetic order, whereas the thermodynamic properties and the phonons are similarly affected by the fluctuations. The discrepancies between microscopic and macroscopic properties are largest at T_C . However, they are significant also below. We recall that the Grüneisen parameter turns negative right above $T_{\rm C}$ meaning that the phonon frequencies anomalously increase along with the volume. In the case of MnSi this anomaly in *γ*macro can be traced back to the thermal expansion [\[32,65\]](#page-17-0). The strong discrepancies between microscopic and macroscopic properties highlight that the global volume changes observed around $T_{\rm C}$ are insufficient to explain the phonon anomalies. Rather, there are interactions that leave a much stronger imprint on the phonons studied here than on the overall bulk properties. In fact, Fawcett *et al.* [\[31,66\]](#page-17-0) found large magnetic contributions in studies of the specific heat and the elastic properties below T_C which they interpreted in terms of a magnetic Grüneisen parameter γ_{mag} . The authors found a γ_{mag} as large as -45 and constant in a temperature range from 14 to 32 K except for significant deviations very near to T_C . Also, Pfleiderer and co-workers argue that there is a sizable anomalous contribution to the thermal expansion beyond the conventional T^2 variation [\[65\]](#page-17-0).

FIG. 6. (Color online) Difference of the experimental phonon energies $\omega_{\rm ph}(T)$ and those calculated via Eqs. [\(5\)](#page-6-0) and [\(9\)](#page-7-0) using $\gamma_{\text{macro}}(T)$. Note the logarithmic temperature scale. The anomalies above $T_{\rm C}$ vanish almost completely while those at $T_{\rm C}$ have no correspondence in the thermodynamical properties.

In contrast to the itinerant helimagnet MnSi studied here, the understanding of the spin-phonon interaction in insulating magnets is much more advanced as shown in various publications [\[62–64\]](#page-17-0). There, the temperature dependence of the phonon energies can be readily described by the mean-fieldlike variation of the macroscopic magnetization. A similar proportionality may be compatible with the data of the $T_2^{(314)}$ line [Fig. $5(c)$] below T_C but not for any of the other lines. The anomalies found in the fluctuation range ($T_C < T < 32$ K) can not be explained in this scenario. Similarly, the nonmonotonic variation of the phonons $E^{(194)}$, $T_2^{(197)}$, and $E^{(318)}$ in the low-temperature limit need further attention. We conclude that the four phonon lines studied here exhibit unexpected features in the fluctuation range right above T_C , at the transition, and in the ordered state below T_C which do not have a correspondence in Heisenberg-type magnets.

B. Carrier properties

We now derive and discuss electronic properties from the Raman continua examples of which are shown in Fig. [3.](#page-5-0) It is a standard procedure in optical (IR) spectroscopy to derive transport lifetimes $\tau(\omega, T)$ or scattering rates $\Gamma = 1/\tau$ as well as the optical mass $m^*/m_b = 1 + \lambda(\omega, T)$ from the reflectivity [\[67,68\]](#page-17-0) or from ellipsometry data. Since the current response is typically not very **k** selective, IR yields only averages over the entire Fermi surfaces. However, if the single-particle relaxation depends on the momentum **k**, as expected for MnSi [\[43\]](#page-17-0), some momentum resolution may be similarly useful as in the cuprates, for instance [\[49\]](#page-17-0).

For this reason, electronic Raman scattering can provide additional information [\[36\]](#page-17-0). For the normal state, Opel and co-workers [\[49\]](#page-17-0) demonstrated that the relaxation or memory function approach proposed by Götze and Wölfle $[69]$ $[69]$ theoretically and worked out for IR spectroscopy by Allen and Mikkelsen [\[67\]](#page-17-0) can be adapted to facilitate the derivation of lifetimes $\tau_{\gamma\gamma}(\omega, T)$ or scattering rates $\Gamma_{\gamma\gamma} = 1/\tau_{\gamma\gamma}$ and mass enhancement factors $1 + \lambda_{\gamma\gamma}(\omega, T)$ from the electronic continuum (see Fig. [3\)](#page-5-0) that is part of the total response $R\chi''_{\gamma\gamma}$. Opel *et al.* showed in particular that absolute numbers for all quantities can be obtained. In the context here, *γ* is shorthand for $\gamma(\mathbf{k})$ and represents the Raman vertex or form factor which projects out symmetry-dependent parts of the Brillouin zone. For simplicity and in order to avoid confusion with the Grüneisen parameters, we label the derived quantities by the symmetry projection μ rather than the vertex γ .

For the analysis of the electronic part, we use symmetryresolved spectra such as those shown in Fig. [3.](#page-5-0) There, one realizes that the continuum in $\mu = T_1$ symmetry is approximately as strong as those in the other symmetries. However, excitations having T_1 symmetry (similarly as A_{2g} excitations in tetragonal systems) correspond to antisymmetric off-diagonal elements in the Raman tensor α which are present whenever the off-diagonal elements are not equal, $\alpha_{i,j} \neq \alpha_{j,i}$. In the nonresonant Raman response, continuous T_1 contributions are expected to be absent in nonmagnetic metallic systems and are usually found to be weak [\[70\]](#page-17-0). Here, they are relatively strong but can not be identified unambiguously as discussed in detail in Appendix [E.](#page-15-0) Therefore, while showing the results of the memory function analysis, that remains valid for energy-dependent relaxation processes, we can discuss possible implications of the T_1 response only on a preliminary level.

Figure [7](#page-10-0) shows the dynamical relaxation rates $\Gamma_{\mu}(\omega, T)$ derived from the energy-dependent response $R\chi^{\prime\prime}_{\mu}(\omega,T)$ (Fig. [3\)](#page-5-0) as described in Ref. [\[49\]](#page-17-0). They all have a similar temperature dependence at high energies but exhibit substantial differences close to zero energy. While Γ_{T1} , and Γ_{T2} become rather flat at room temperature, Γ_{A1} dips down at low energy, thus reducing the overall temperature dependence between 13 and 288 K. In contrast, $\Gamma_E(288 \text{ K})$ increases slightly towards low energy. The rates reflect the variation of the raw data (Fig. [3\)](#page-5-0) but, owing to the derivation procedure [\[49\]](#page-17-0), show some features in a more pronounced fashion such as the low-energy variation with temperature.

For being derived from $R\chi^{\prime\prime}_{\mu}(\omega,T)$ in the same way, the dynamical mass renormalization factors $1 + \lambda_{\mu}(\omega, T) =$ $m^*_{\mu}(\omega, T)/m_b$, where m_b is the band mass, are expected to similarly emphasize the variations close to zero energy. In fact, Fig. [8\(b\)](#page-10-0) shows an anomaly of $1 + \lambda_E(\omega, T)$ at 288 K. While all other masses increase monotonically with decreasing energy (other panels of Fig. [8\)](#page-10-0), as typically expected for metals,

 $1 + \lambda_E(\omega, 288\text{K})$ is reduced and even becomes negative at low energies. On the high-energy side, the masses saturate between 1 and 2 as expected. For the A_1 , T_1 , and T_2 symmetries, the masses decay monotonically. In the zero-energy limit they reach temperature-dependent values between 0.8 (T_2) and 5 (A_1) .

The dynamical carrier properties found here with light scattering are in overall agreement with those derived from the reflectivity [\[42\]](#page-17-0). While the magnitudes and temperature dependencies of $\Gamma_{\mu}(\omega,T)$ and $1 + \lambda_{\mu}(\omega,T)$ are similar below 300 K, there are important differences which may lead to new insights: (i) The masses found here are generally above unity indicating the existence of interactions at all temperatures and energies. (ii) The symmetry dependence is significant. This is a unique feature of light scattering and indicates the existence of anisotropies in the Brillouin zone which can not be derived from the optical conductivity.

However, as opposed to the cuprates [\[36,37\]](#page-17-0) or the ironbased compounds $[70,71]$, it is not as straightforward to directly map the symmetries on separate bands or regions in the Brillouin zone since only three of the seven Fermi surfaces are in high-symmetry positions around the $\Gamma(0,0,0)$ and *R* (π, π, π) points [\[72\]](#page-17-0). The four other Fermi surfaces have similar shapes and can be thought of as being built of three tubes intersecting around the Γ point. For the reader's convenience, all Fermi surfaces are shown in Fig. [15.](#page-15-0) In general, the minority- and majority-spin Fermi surfaces can not be distinguished. However, according to the lowest-order Brillouin zone harmonics for cubic crystals [\[73\]](#page-17-0), carriers on the Fermi surfaces around the Γ and R points may be projected out predominantly in *A*¹ symmetry. In addition, the lowest-order nontrivial A_1 vertex $\gamma_{A1}^{(1)} = \cos k_x + \cos k_y + \cos k_z$ has its nodes very close to the big tubular Fermi surfaces. This means that they should contribute predominantly to the E and T_2 spectra. For example, the *E* spectra are dominated by the necks around the *X* points, $(\pi, 0, 0)$ and the T_2 spectra are more sensitive in the centers of the octants. More detailed information about the projections may be obtained by calculating the band curvatures which yield the sensitivities for a given band structure in the nonresonant case [\[37,71\]](#page-17-0). In any case, the selection rules suggest that the electronic interactions in MnSi have a mild dependence on the band index and on momentum on an individual band.

While the results in the A_1 and T_2 symmetries are compatible with metallic behavior at all temperatures, the *E* spectra deviate remarkably from what one expects for a metal. The deviation is seen best in the dynamics of the mass at 288 K which varies nonmonotonically. At room temperature, this observation is paralleled by the IR results reported by Mena *et al.* [\[42\]](#page-17-0). Not surprisingly, it survives down to lower temperatures in the Raman spectra since the Brillouin zone projections are more selective.

As to the interpretation, the relaxation rates are more intuitive. The increase towards zero energy indicates either a new relaxation channel or pseudogaplike behavior at higher temperatures. Similar anomalies have in fact been observed in organic conductors [\[74\]](#page-17-0) and cuprates [\[75\]](#page-17-0). For heavy-fermion systems, this type of temperature dependence can be explained in terms of a Kondo-type interaction [\[76\]](#page-17-0). However, it is unusual that the anomaly appears here at high temperature and

FIG. 7. (Color online) Temperature and symmetry dependence of the relaxation rates $\Gamma_{\mu}(\omega, T)$. The rates were obtained from the electronic continua as shown in Fig. [3.](#page-5-0) To calculate $\Gamma_{\mu}(\omega, T)$, the procedure described by Opel and co-workers [\[49\]](#page-17-0) was used. The smooth lines are phenomenological fits to the data according to Eq. (11) .

vanishes below 100 K. Obviously, at least parts of the Fermi surface exhibit insulating behavior at higher temperature. Whether or not this can be observed in ordinary transport remains open at the moment since there are no data available at elevated temperature. In addition, the metallic parts could short circuit the insulating ones in a similar fashion as in the cuprates [\[77\]](#page-17-0). We note that a vanishing or even negative mass [Fig. $8(b)$] can also result from multiband effects which,

FIG. 8. (Color online) Temperature and symmetry dependence of the optical masses $1 + \lambda_{\mu}(T)$ obtained via the same formalism as the relaxation rates. The smooth lines are derived from the fits to the relaxation rates via Kramers-Kronig transformation, hence obey causality (see text). They are in reasonable agreement to the data except for a constant offset.

however, need to be studied numerically on the basis of a realistic band structure.

We now focus on the static (dc) limit. To reliably extract the zero-energy extrapolation values of $\Gamma_{\mu}(\omega \to 0, T)$ and 1 + $\lambda_{\mu}(\omega \to 0, T)$ from the relatively noisy data (cf. Sec. [II\)](#page-1-0), we use phenomenological functions having the correct analytical behavior in the limits $\omega \to 0$ and $\omega \to \infty$: (i) $\Gamma_{\mu}(\omega, T)$ (as opposed to the imaginary part of the single-particle selfenergy Σ'') is a symmetric function $\Gamma_{\mu}(-\omega,T) = \Gamma_{\mu}(\omega,T)$, (ii) $\lambda_{\mu}(\omega \to 0, T > 0)$ is finite, and (iii) $\Gamma_{\mu}(\omega, T)$ saturates at high energy. The latter condition is a restriction in the spirit of the Mott-Joffe-Regel limit which, strictly speaking, applies only for single-particle lifetimes. In the case of two-particle response functions, there are contributions to the carrier response beyond the mean-free path, and general statements as to the high-energy behavior become impossible [\[78\]](#page-17-0). Since most of the relaxation rates derived here saturate, the introduction of a temperature-dependent limiting value $\Gamma_{\mu}^{\max}(T)$ is justified experimentally but is not well supported theoretically.

On this basis, the minimal model is the parallel-resistor formalism with a quadratic energy dependence at $\omega \rightarrow 0$ [\[79\]](#page-17-0):

$$
\frac{1}{\Gamma_{\mu}(\omega,T)} = \frac{1}{\Gamma_{\mu}^*(\omega,T)} + \frac{1}{\Gamma_{\mu}^{\max}(T)},
$$
(10)

where $\Gamma^*_{\mu}(\omega, T) = c(T) + a(T)\omega^2$ dominates at low frequencies while $\Gamma_{\mu}^{\max}(T)$ describes the high-energy part. Inversion yields

$$
\Gamma_{\mu}(\omega, T) = \frac{[c(T) + a(T)\omega^2] \Gamma_{\mu}^{\max}(T)}{c(T) + a(T)\omega^2 + \Gamma_{\mu}^{\max}(T)},
$$
(11)

with the zero-frequency limit $\Gamma_{\mu}(0,T)$ given by

$$
\Gamma_{\mu}(0,T) = \frac{c(T)\Gamma_{\mu}^{\max}(T)}{c(T) + \Gamma_{\mu}^{\max}(T)}.
$$
\n(12)

The fits to the relaxation rates $\Gamma_{\mu}(\omega, T)$ according to Eq. (11) are shown in Fig. [7.](#page-10-0) As expected, the $\omega \rightarrow 0$ extrapolation [Eq. (12)] depends on both the high-frequency limit $\Gamma_{\mu}^{\max}(T)$ and the offset $c(T)$. Each point in Fig. 9 is obtained from such a dc extrapolation of $\Gamma_{\mu}(\omega,T)$.

The static Raman relaxation rates $\Gamma_{\mu}(0,T)$ can be compared to the longitudinal dc resistivity $\rho(T)$. To this end, we show the resistivity measured on a comparable sample on the right axis of Fig. 9. In a Drude model, the resistivity is related to the carrier relaxation rate $\Gamma_{\rho}(T) = \hbar / \tau(T)$ via the plasma frequency ω_{pl} as $\Gamma_{\rho}(T) = \epsilon_0 \omega_{\text{pl}}^2 \rho(T)$ with the vacuum permeability ϵ_0 and $\omega_{\text{pl}} = 2.3$ eV [\[42\]](#page-17-0). An additional factor of 0.73 was introduced to match $\Gamma_{\rho}(T)$ and $\Gamma_{\mu}(\omega = 0, T)$ (see Fig. 9). A factor smaller than one can be explained by the frequency cutoff at 400 cm^{-1} in the relaxation rate analysis (Fig. [7\)](#page-10-0). In addition, it can not be expected that the relaxation rates obtained from the light scattering experiment and from transport coincide completely since the higher-order corrections to the respective response are different and in the 10% range [\[81\]](#page-17-0). The Raman data points $\Gamma_{\mu}(0,T)$ in $\mu = E$, *T*₁, and *T*₂ symmetry agree with $\Gamma_{\rho}(T)$ in the temperature range from 310 to 30 K. The experimental error of about ± 30 cm⁻¹ was estimated from the scatter of neighboring points and the error of the dc extrapolation of $\Gamma_{\mu}(\omega,T)$, plotted in Fig. [7.](#page-10-0) It is remarkable that also the relaxation rates in T_1 symmetry, which may reflect properties of chiral excitations, follow the resistivity curve at high temperatures. Provided that the T_1 symmetry projects in fact chiral excitations (for a further discussion, see Appendix E), one can argue that chiral excitations are allowed also above T_C where no helimagnetic order is present because also in the high-temperature phase the crystal structure lacks inversion symmetry. Thus, chiral excitations could be created with inelastic photon scattering even up to room temperature as anticipated in Ref. [\[32\]](#page-17-0).

FIG. 9. (Color online) Static Raman relaxation rates and transport data. Panel (a) shows the Raman relaxation rates $\Gamma_{\mu}(\omega = 0, T)$ (points, left axis) as a function of symmetry μ as derived from $\Gamma_{\mu}(\omega,T)$ (see text). If the longitudinal dc resistivity $\rho(T)$ (black line, right axis) [\[80\]](#page-17-0) is converted into a relaxation rate $\Gamma_{\rho}(T)$ using a Drude model with the experimental plasma frequency $\omega_{\text{pl}} = 2.3 \text{ eV}$ [\[42\]](#page-17-0), an extra factor of 0.73 is needed to match transport and Raman data. Above T_c (dashed vertical line), the Raman data in E , T_1 , and T_2 symmetry agree with $\rho(T)$, while the data in A_1 symmetry do not. (b)–(e) Zoom in on low temperatures. The phase transition has only a minor effect on $\Gamma_{\mu}(\omega = 0, T)$. Above $T_{\rm C}$ close to the fluctuation-disordered regime (shaded), there may be a dip in *A*¹ and T_2 symmetry. Below the phase transition $\Gamma_\mu(\omega = 0, T)$ decreases slower than Γ _{*o*} (T) .

However, as discussed in the Appendices, a final interpretation of the T_1 data is premature.

The A_1 symmetry component of the light scattering susceptibility, which has always an isotropic part, is screened by long-range Coulomb interaction in the limit $q \rightarrow 0$. This is referred to as backflow, required to comply with particlenumber conservation and gauge invariance in crystals with free charge carriers [\[37\]](#page-17-0). This screening effect may be one reason why the *A*¹ symmetry component of the dc relaxation rates does not match the resistivity data. The nodes of the first nontrivial A_1 vertex may be another one since they black out the response from the big Fermi surface and highlight that from the small Fermi surfaces enclosing Γ and R , as described above and in Appendix [F.](#page-16-0) Progress is probably only possible if the data are analyzed with a phenomenological model and on the basis of a realistic band structure.

Below $T_{\rm C}$ the Raman relaxation rates for all symmetries stay well above the transport data and decrease at a lower rate but, finally become very small and, at least in E and T_2 symmetry, approach values close to what one expects from the transport. The observation of this decrease makes it unlikely that the saturation observed in IR [\[42\]](#page-17-0) or in the other symmetries is an artifact resulting from the rather small relaxation rates, and we conclude that the discrepancies between IR, transport, and Raman scattering in the ordered state need to be taken seriously. More specifically, the convex and the concave T^2 -like behavior found in Raman and, respectively, in ordinary transport seem to be two sides of the same coin which need to be explained theoretically. Finally, it is interesting to note that in the temperature range of the skyrmion phase $(26-28 \text{ K})$ [\[82\]](#page-17-0), exhibiting a topological Hall signal [\[25,26\]](#page-16-0), all Raman relaxation rates are in the range 100–150 cm[−]¹ and temperature independent. This experimental observation supports the assumption of an approximately momentumindependent carrier lifetime in the theoretical description of the topological Hall signal [\[83,84\]](#page-17-0)

Similarly surprising is the anomaly right above $T_{\rm C}$ which is particularly pronounced in T_2 symmetry [Fig. $9(e)$] but probably present also in *A*¹ and *E* symmetry. It goes along with the dip in the phonon frequencies (Figs. [4](#page-5-0) and [5\)](#page-6-0). The simultaneous observation of the anomaly in the phonon energy and in the electronic continuum at the same temperature makes us confident that the effect is significant. While the anomaly in the phonon channel is also observed independently in the Grüneisen parameter as derived from the thermal expansion, the nonmonotonic variation in the carrier relaxation is a new observation underpinning the impact of the phase transition and the preceding fluctuations on the electrons. The detailed analysis below 40 K clearly reveals unexpected interactions between spin, charge, and lattice at the phase transition.

V. CONCLUSIONS

We have studied phonons and electronic excitations in MnSi by Raman spectroscopy. The phonons show conventional behavior above the helimagnetic transition but exhibit pronounced anomalies slightly above and below *T*_C. Most remarkably, the phonon energy dips down already at 31 K clearly above the transition. This anomaly is tracked by the Grüneisen parameter. At T_C the phonon energy first recovers and then softens before increasing at the lowest temperatures. Hence, the temperature dependence at and below T_C has no correspondence in the thermodynamic properties and may indicate that the optical phonons scrutinized here couple to the spin order directly rather than via magnetostriction effects. In an applied magnetic field of 4 T, in the field polarized state, the phonon anomalies disappear. This suggests a connection of the anomalies and helimagnetism.

The electronic relaxation rates in E and T_2 symmetry agree reasonably well with conventional transport above 31 K. Significant deviations are only found in the range $4 < T < 31$ K. However, theoretical support is required to understand these deviations from conventional transport and their symmetry

dependence. The narrow minimum at $T_{\rm C} + 2$ K highlights the importance of the fluctuation range for the phase transition.

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APPENDIX A: EXPERIMENTAL SETUP

For excitation a solid-state laser emitting at 532.3 nm was used. The light path in the vicinity of the sample is sketched in Fig. 10. The incoming beam passes a polarizer (1) and a Soleil-Babinet compensator (2) to prepare the light polarization such that the photons inside the sample have the proper polarization state. Since the incoming light is focused on the sample surface

FIG. 10. (Color online) Sketch of the light path close to the sample. With a polarizer (1) and a Soleil-Babinet compensator (2), the polarization and phase of the incoming laser light (dark green) can be adjusted. The laser light is directed via a prism (3) to an achromat (4) focusing on the sample surface (6). Since separate optical components are used for excitation and collection, the direct reflex (7) from the mirrorlike sample surface does not enter the collection optics (8) ($f \approx 30$ mm, N.A. = 0.34) for the scattered light (light green). Reflexes from the cryostat windows (5) are blocked separately. This considerably reduces the amount of elastically scattered light and fluorescence reaching the spectrometer. The residual background signal is further reduced by a spatial filter (9) in the path of the scattered light consisting of two confocal achromatic lenses ($f = 75$ mm) and a circular aperture of 150 μ m in the common focus. A quarter wave plate (10) and an analyzer (11) select the polarization of the scattered light. The sample is located in a He-flow cryostat in the center of a superconducting solenoid (12).

at an angle of 30◦, the absorption of photons polarized parallel and perpendicular to the plane of incidence is not equivalent. Circularly polarized light, for example, assumes an elliptical polarization inside the sample. The Soleil-Babinet compensator (2) takes care of this problem by facilitating independent access to polarization and phase [\[45\]](#page-17-0). In terms of the example above, the light is elliptically polarized outside the sample such that the absorbed light is circularly polarized inside the sample. To this end, one has to keep track of all optical elements in the light path. The major effect comes from the sample surface and is determined by the complex index of refraction \hat{n} (cf. Sec. [II A\)](#page-1-0). Via a mirror and a prism (3) the photons are directed to an achromat (4) and focused on the sample surface (6). The angle of incidence of 30◦ guarantees that the photons reflected (7) off the sample surface do not enter the collection optics (8). In this configuration, the contributions from fluorescence in the optics and from the laser light are minimized. The Raman light is collected by a custom-made objective lens (8) having a numerical aperture of N.A. = 0*.*34 corresponding to a solid angle of 0.37 sr. For maximal throughput and best imaging properties, the geometrical aberrations introduced by the cryostat windows (5) are corrected by the objective lens (8). In this way, the scattered light can be spatially filtered (9) without excessive losses. The objective (8) and the spatial filter (9) are the key parts which facilitate measurements on samples with very few scattered photons. The scattering geometry is dictated by a solenoid (12) which allows us to apply magnetic fields up to 8 T.

Before the scattered photons arrive at the entrance slit of the spectrometer the desired polarization states are selected with a quarter wave plate (10) and an analyzer (11). For dispersion a triple-stage spectrometer (Jobin-Yvon T64000) with the spectral resolution set at approximately 2 cm[−]¹ is used. The transmitted photons are recorded with a liquid-nitrogen-cooled charge coupled device (CCD) detector.

APPENDIX B: TEMPERATURE DETERMINATION

The physical properties depend crucially on the temperature in the illuminated spot T_s . The absorbed light heats the sample locally and induces a sizable difference ΔT between the holder temperature T_h and T_s , particularly at low temperatures. In the main paper, T_s is referred to as T for simplicity. A precise temperature determination is essential to decide if anomalies in the spectra close to T_C are actually appearing above, at, or below the transition.

One common method to determine the amount of heating is to compare Stokes and anti-Stokes intensity, i.e., energygain and energy-loss spectra. They differ by an exponential factor due to thermal occupation which can in principle be used to compute the temperature. However, this method is not always reliable, in particular at temperatures below 100 K and in materials such as MnSi with low scattering intensities. Alternatively, strongly temperature-dependent features in the spectra can be analyzed using combinations of various laser powers *P*abs and holder temperatures *T*h. Ideally, *P*abs and *T*^h are selected in a way that the spectral features assume the same shape for at least two combinations. Then, if ΔT is moderate, one can expect that the spot temperatures are equal. However,

there are no strongly temperature-dependent features in the spectra of MnSi throughout the whole temperature range.

The laser heating used here was determined from previous results on V_3Si [\[46,47\]](#page-17-0). There, the strong temperature dependence of the gap mode in the superconducting state was used to determine the amount of laser heating. Together with data for the thermal conductivity $\lambda(T)$ the complete temperature range of a material becomes accessible. This method can be used for other materials having isotropic heat conduction by appropriately taking into account \hat{n} and $\lambda(T)$. The extrapolation of this procedure worked for $Nb₃Sn$ [\[47\]](#page-17-0). Noticing that MnSi, while not having sufficiently temperaturedependent features, is an isotropic metal, we apply that procedure and provide a few details.

The starting point is the equation for thermal conductivity in semispherical geometry. The laser power P_{abs} is deposited within the illuminated spot with radius r_0 . It is assumed that the complete energy is transferred to the sample holder via heat conduction in the sample. This is an excellent approximation for metals in both vacuum and gas atmosphere, but probably not when the sample is immersed in superfluid He. In the case of transport in the metal, the heat flow through a shell with area $2\pi r^2$ and thickness *dr* is given by

$$
P_{\text{abs}} = -\lambda(T)2\pi r^2 \frac{dT}{dr},\tag{B1}
$$

where dT is the temperature drop across the radial increment dr . If the sample is large compared to r_0 , integration

FIG. 11. (Color online) Temperature determination from thermal conductivity. (a) Thermal conductivity measurement; (b) integrated thermal conductivity. According to Eq. [\(B2\)](#page-14-0), the integral $\int \lambda dT =: \alpha$ from T_h to $T_h + \Delta T$ is constant as long as the laser power and the focus size are not changed. For the experimental setup used here, *α* is 6.4 W/m for an absorbed laser power of 4 mW. The inset of (b) illustrates how ΔT can be obtained from α and the integrated conductivity.

FIG. 12. (Color online) Temperature dependence of the laser heating ΔT for an absorbed laser power of 4 mW. Points correspond to the laser heating for various holder temperatures T_h and are determined from the integrated thermal conductivity as described in Fig. [11.](#page-13-0) An exponential fit was used to obtain ΔT in the full temperature range.

yields [\[47,85\]](#page-17-0)

$$
\alpha(P_{\text{abs}}, r_0) := \frac{P_{\text{abs}}}{2\pi r_0} = \int_{T_{\text{h}}}^{T_{\text{h}} + \Delta T} \lambda(T) dT.
$$
 (B2)

T^h is measured with a Cernox resistor having a vanishingly small magnetoresistance of less than 0.2% for magnetic fields up to 4 T. $\Delta T = T_s - T_h$ is the average laser-induced heating. α depends only on r_0 and P_{abs} but not on any strongly temperature-dependent property of the sample. Hence, the knowledge in one sample, such as V_3Si , is sufficient for deriving ΔT of other compounds. The main nontrivial sample dependence comes from $\lambda(T)$ which has to be known in detail. Then, ΔT can be determined for any T_h if the integral over $\lambda(T)$ is known (cf. Fig. [11\)](#page-13-0).

In V₃Si $\alpha_{V_3Si} = 0.96 \,\mathrm{W/m}$ was derived experimentally for an absorbed laser power of 1 mW. For MnSi, we used $P_{\text{abs}} =$ 4*.*0 mW for all light polarizations. Differences in the optical setup of both experiments change the focus size by a factor of 0.6. Scaling α_{V_3Si} with these changed experimental parameters results in $\alpha_{MnSi} = 6.4 \text{ W/m}$. As an example, the graphical solution of Eq. $(B2)$ for the MnSi sample is shown in Fig. [11.](#page-13-0) The experimental quantity $\alpha_{MnSi} = 6.4 \text{ W/m}$ for $P_{abs} = 4 \text{ mW}$ is added to the integrated thermal conductivity at the holder temperature T_h . Then, a horizontal line intersects the integral $\int \lambda dT$ at the spot temperature T_s . The length of this line is ΔT . In the example of Fig. [11,](#page-13-0) $T_h = 30$ K, $T_s = 31.3$ K, and $\Delta T = 1.3$ K.

In the same way, the laser heating was determined at several different holder temperatures between 4 and 300 K. These temperatures are indicated as points in Fig. 12. An exponential fit yields ΔT for all temperatures in-between and was used to correct for the laser heating in all measurements presented here. At selected holder temperatures $T_h = 2, 30,$ and 300 K, ΔT is 2.9, 1.3, and 0.4 K, respectively, for $P_{\text{abs}} = 4$ mW.

FIG. 13. (Color online) Fit of the data on the example of an *xx* spectrum at 17 K. Panel (a) shows the measured data (green) together with the fit function (orange) consisting of a fifth-order polynomial and four Voigt shaped peaks. (b) Shows the difference (blue) between measurement and fit. A smoothed curve (red) points out how much and at which frequencies the measurement and the fit differ beyond the noise level. To separate the phononic part from the electronic continuum, only the fits of the peaks are subtracted from the spectra.

APPENDIX C: DATA ANALYSIS

Another caveat in the analysis, connected with the low scattering intensity, is the fitting procedure used to separate the phononic contribution from the electronic continuum. Figure 13 shows a typical example. The Raman response $R\chi''$ (green) is fitted (orange) by a polynomial baseline superimposed by several Voigt shaped peaks. The baseline is a fifth-order polynomial fitted to 30 anchor points which are distributed in the full energy range, but not close to the peak positions. The baseline is subtracted to put the peaks on a horizontal ground for the Voigt fit. Figure 13(b) shows the difference (blue) between the data and the fit which is less than 0.005 counts $(s mW)^{-1}$ for most points. The smoothed line (red) is a guide to the eye. To get the electronic continua shown in Fig. [3,](#page-5-0) only the Voigt part of the fit at zero background is subtracted.

APPENDIX D: GRUNEISEN PARAMETER ¨

The macroscopic Grüneisen parameter γ_{macro} can be determined from experimentally accessible thermodynamic properties [\[58\]](#page-17-0)

$$
\gamma_{\text{macro}}(T) = \frac{3\alpha(T)K(T)V^{\text{mol}}(T)}{C_p^{\text{pol}}(T)}.
$$
 (D1)

The published data on thermal expansion, bulk modulus, and heat capacity were sampled in 1-K steps and then used to calculate γ_{macro} [\[11,](#page-16-0)[30,33,61\]](#page-17-0). For $T \rightarrow 0$, γ_{macro} is expected to vanish (dots in Fig. [14\)](#page-15-0) as α goes to zero. At temperatures

FIG. 14. (Color online) Grüneisen parameters in MnSi. The macroscopic Grüneisen parameter $\gamma_{\text{macro}}(T)$ (green) as derived from thermodynamic properties in comparison with the constant phonon Grüneisen parameter $\gamma_i = 2.5$ (orange) which describes the thermal expansion shift of the Raman mode *i*.

below T_c , γ _{macro} is negative with the minimum of about -20 at $T_{\rm C}$. Above the transition, there is a steep increase and a sign change. *γ*macro reaches a maximum of 7 at 36 K and then approaches a value of 2.5 with increasing temperatures. This is compatible with the phonon Grüneisen parameter γ_i derived from the thermal expansion shift of the Raman modes at elevated temperatures (Sec. [IV A\)](#page-5-0).

APPENDIX E: CONTRIBUTIONS IN *T***¹ SYMMETRY**

Contributions in T_1 symmetry can arise either if there is a background from light sources other than the sample or close to resonances or if the chiral symmetries of the initial and the excited states are different. (i) There are various possibilities for external light sources (other than Raman scattering from the sample) such as fluorescence in the optical elements or residual light in the laboratory or background signal of the CCD. The CCD background was determined experimentally with closed shutter. Similarly, spectra were taken with open shutter and blocked laser for checking the residual light. The two results were found to be identical indicating that the residual light level is negligible. The CCD background was subtracted from the measured spectra. Without spatial filtering (element 9 in Fig. [10\)](#page-12-0), the fluorescence from optical elements is approximately as strong as the signal. With pinhole a reduction of at least 90% can be achieved. In addition, we compared the spectra measured in the magnet cryostat close to backscattering conditions with those obtained in pseudo-Brewster geometry, where no laser light reaches the collection optics, and found good agreement. Therefore, the background problem can be considered under control. (ii) Away from resonances when the photon energies $\omega_{I,S}$ can be neglected with respect to the gaps between the electron bands around the Fermi energy, $\omega_{I,S} \ll |\varepsilon_n(\mathbf{k}) - \varepsilon_m(\mathbf{k} + \mathbf{q})|$, the effective mass approximation applies [\[37\]](#page-17-0), and one does not expect a response from electron-hole excitations in T_1 (or, in tetragonal systems, A_{2g}) symmetry [\[86\]](#page-17-0) simply because the order of the partial derivatives of the conduction band $\varepsilon_c(\mathbf{k})$ is irrelevant. Since in second-order perturbation theory with $\omega_{I,S} > 0$ the matrix elements linear in the vector potential \mathbf{A} , M_{xy} and M_{yx} , are usually not identical, meaning that $|M_{xy} - M_{yx}|^2 > 0$, one expects small but finite intensity in the T_1 channel. Large intensity may occur close to a narrow resonance. (iii) If the chiral symmetry of the initial and the final states are different such as in the case of crystal-field excitations for instance [\[48\]](#page-17-0) some of the matrix elements are antisymmetric. In 1990, Shastry and Shraiman [\[87\]](#page-17-0) derived the magnetic Raman response for a Mott-Hubbard system and found that the chirality operator $S_i \cdot (S_j \times S_k)$ couples to the light in linear order and has antisymmetric matrix elements. Later Michaud, Vernay, and Mila showed that this is not the case due to cancellation effects [\[88\]](#page-17-0). Nevertheless, scattering from chiral spin excitations is likely to be observed experimentally at least in Heisenberg magnets [\[89\]](#page-17-0) and may come from higher-order excitations or strong resonance enhancement. On the basis of the existing data the problem can not be settled satisfactorily for any of the systems studied so far.

FIG. 15. (Color online) (a) Majority-spin and (b) minority-spin Fermi surfaces of MnSi (without spin-orbit coupling) as derived by Jeong and Pickett [\[72\]](#page-17-0). (c) Nodal hypersurface of the lowest-order *A*¹ Raman vertex.

In summary, while contributions from residual light in the laboratory and from fluorescence can safely be excluded to be at the origin of the observed T_1 spectra, it is complicated to cleanly distinguish between resonance effects and chiral excitations. Either the intensity comes from chiral spin excitations due to higher-order scattering processes or results from the inequivalence of the matrix elements M_{xy} and M_{yx} due to resonance effects. In the latter case, a similarity of the T_1 and the T_2 spectra can be expected and is not very interesting. In the other case, one could say that chiral and carrier excitations have a similar temperature dependence indicating some so far unexplained interrelation and possibly far-reaching conclusions. Since the memory function approach does not *a priori* specialize to a specific type of excitations, it can, at least formally, be applied also in T_1 symmetry. However, for the reasons explained here, we wish to be conservative and do not analyze the T_1 results in detail. In fact, a study of the resonance behavior of the T_1 continuum using various laser lines for excitation would be a major step towards a clarification and should precede the interpretation.

- [1] T. Moriya, *Spin Fluctuations in Itinerant Electron Magnetism* (Springer, Berlin, 1985).
- [2] G. G. Lonzarich and L. Taillefer, [J. Phys. C: Solid State Phys.](http://dx.doi.org/10.1088/0022-3719/18/22/017) **[18](http://dx.doi.org/10.1088/0022-3719/18/22/017)**, [4339](http://dx.doi.org/10.1088/0022-3719/18/22/017) [\(1985\)](http://dx.doi.org/10.1088/0022-3719/18/22/017).
- [3] G. R. Stewart, [Rev. Mod. Phys.](http://dx.doi.org/10.1103/RevModPhys.73.797) **[73](http://dx.doi.org/10.1103/RevModPhys.73.797)**, [797](http://dx.doi.org/10.1103/RevModPhys.73.797) [\(2001\)](http://dx.doi.org/10.1103/RevModPhys.73.797).
- [4] H. v. Löhneysen, A. Rosch, M. Vojta, and P. Wölfle, Rev. Mod. Phys. **[79](http://dx.doi.org/10.1103/RevModPhys.79.1015)**, [1015](http://dx.doi.org/10.1103/RevModPhys.79.1015) [\(2007\)](http://dx.doi.org/10.1103/RevModPhys.79.1015).
- [5] C. Pfleiderer, P. Böni, T. Keller, U. K. Rößler, and A. Rosch, [Science](http://dx.doi.org/10.1126/science.1142644) **[316](http://dx.doi.org/10.1126/science.1142644)**, [1871](http://dx.doi.org/10.1126/science.1142644) [\(2007\)](http://dx.doi.org/10.1126/science.1142644).
- [6] C. Pfleiderer, S. R. Julian, and G. G. Lonzarich, [Nature \(London\)](http://dx.doi.org/10.1038/35106527) **[414](http://dx.doi.org/10.1038/35106527)**, [427](http://dx.doi.org/10.1038/35106527) [\(2001\)](http://dx.doi.org/10.1038/35106527).
- [7] C. Pfleiderer, D. Reznik, L. Pintschovius, H. v. Löhneysen, M. Garst, and A. Rosch, [Nature \(London\)](http://dx.doi.org/10.1038/nature02232) **[427](http://dx.doi.org/10.1038/nature02232)**, [227](http://dx.doi.org/10.1038/nature02232) [\(2004\)](http://dx.doi.org/10.1038/nature02232).
- [8] Y. J. Uemura, T. Goko, I. M. Gat-Malureanu, J. P. Carlo, P. L. Russo, A. T. Savici, A. Aczel, G. J. MacDougall, J. A. Rodriguez, G. M. Luke, S. R. Dunsiger, A. McCollam, J. Arai, C. Pfleiderer, P. Böni, K. Yoshimura, E. Baggio-Saitovitch, M. B. Fontes, J. Larrea, Y. V. Sushko, and J. Sereni, Phys. Rev. Lett. **3**, 29 (2007).
- [9] S. A. Brazovskii, Sov. Phys. JETP **41**, 85 (1975).
- [10] M. Janoschek, M. Garst, A. Bauer, P. Krautscheid, R. Georgii, P. Boni, and C. Pfleiderer, *[Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.87.134407)* [87](http://dx.doi.org/10.1103/PhysRevB.87.134407), [134407](http://dx.doi.org/10.1103/PhysRevB.87.134407) [\(2013\)](http://dx.doi.org/10.1103/PhysRevB.87.134407).
- [11] A. Bauer, M. Garst, and C. Pfleiderer, [Phys. Rev. Lett.](http://dx.doi.org/10.1103/PhysRevLett.110.177207) **[110](http://dx.doi.org/10.1103/PhysRevLett.110.177207)**, [177207](http://dx.doi.org/10.1103/PhysRevLett.110.177207) [\(2013\)](http://dx.doi.org/10.1103/PhysRevLett.110.177207).
- [12] S. Mühlbauer, B. Binz, F. Jonietz, C. Pfleiderer, A. Rosch, A. Neubauer, R. Georgii, and P. Böni, [Science](http://dx.doi.org/10.1126/science.1166767) [323](http://dx.doi.org/10.1126/science.1166767), [915](http://dx.doi.org/10.1126/science.1166767) [\(2009\)](http://dx.doi.org/10.1126/science.1166767).
- [13] W. Münzer, A. Neubauer, T. Adams, S. Mühlbauer, C. Franz, F. Jonietz, R. Georgii, P. Böni, B. Pedersen, M. Schmidt, A. Rosch, and C. Pfleiderer, [Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.81.041203) **[81](http://dx.doi.org/10.1103/PhysRevB.81.041203)**, [041203\(](http://dx.doi.org/10.1103/PhysRevB.81.041203)R) [\(2010\)](http://dx.doi.org/10.1103/PhysRevB.81.041203).
- [14] C. Pfleiderer, T. Adams, A. Bauer, W. Biberacher, B. Binz, F. Birkelbach, P. Böni, C. Franz, R. Georgii, M. Janoschek, F. Jonietz, T. Keller, R. Ritz, S. Mühlbauer, W. Münzer, [A. Neubauer, B. Pedersen, and A. Rosch,](http://dx.doi.org/10.1088/0953-8984/22/16/164207) J. Phys.: Condens. Matter **[22](http://dx.doi.org/10.1088/0953-8984/22/16/164207)**, [164207](http://dx.doi.org/10.1088/0953-8984/22/16/164207) [\(2010\)](http://dx.doi.org/10.1088/0953-8984/22/16/164207).
- [15] X. Z. Yu, Y. Onose, N. Kanazawa, J. H. Park, J. H. Han, Y. Matsui, N. Nagaosa, and Y. Tokura, [Nature \(London\)](http://dx.doi.org/10.1038/nature09124) **[465](http://dx.doi.org/10.1038/nature09124)**, [901](http://dx.doi.org/10.1038/nature09124) [\(2010\)](http://dx.doi.org/10.1038/nature09124).

APPENDIX F: FERMI SURFACES AND THE *A***¹ RAMAN VERTEX**

Figure [15](#page-15-0) shows the Fermi surfaces of MnSi as derived from band-structure calculations without spin-orbit coupling by Jeong and Pickett [\[72\]](#page-17-0). Figures $15(a)$ and $15(b)$ show the Fermi surfaces for majority and minority spin, respectively. Figure $15(c)$ shows the surface in *k* space on which the lowest-order nontrivial A_1 Raman vertex $\gamma_{A1}^{(1)} = \cos k_x + \gamma_{A1}^{(1)} = \cos k_x$ $\cos k_y + \cos k_z$ derived from Brillouin zone harmonics [\[73\]](#page-17-0) vanishes. Electrons close to this part of the Brillouin zone are not projected out. Hence, only the central pockets and those located on the corners are projected in A_1 symmetry with appreciable intensity. The E and T_2 vertices, in contrast, have finite weight on major parts of the large Fermi surfaces. A distinction between majority and minority bands does not seem to be possible here. Since spin-orbit coupling effects are expected to be small for Mn [\[72\]](#page-17-0), they are unlikely to have an effect on the symmetry-based arguments outlined here.

- [16] X. Z. Yu, N. Kanazawa, Y. Onose, K. Kimoto, W. Z. Zhang, S. Ishiwata, Y. Matsui, and Y. Tokura, [Nat. Mater.](http://dx.doi.org/10.1038/nmat2916) **[10](http://dx.doi.org/10.1038/nmat2916)**, [106](http://dx.doi.org/10.1038/nmat2916) [\(2011\)](http://dx.doi.org/10.1038/nmat2916).
- [17] S. Seki, X. Z. Yu, S. Ishiwata, and Y. Tokura, [Science](http://dx.doi.org/10.1126/science.1214143) **[336](http://dx.doi.org/10.1126/science.1214143)**, [198](http://dx.doi.org/10.1126/science.1214143) [\(2012\)](http://dx.doi.org/10.1126/science.1214143).
- [18] T. Adams, A. Chacon, M. Wagner, A. Bauer, G. Brandl, [B. Pedersen, H. Berger, P. Lemmens, and C. Pfleiderer,](http://dx.doi.org/10.1103/PhysRevLett.108.237204) Phys. Rev. Lett. **[108](http://dx.doi.org/10.1103/PhysRevLett.108.237204)**, [237204](http://dx.doi.org/10.1103/PhysRevLett.108.237204) [\(2012\)](http://dx.doi.org/10.1103/PhysRevLett.108.237204).
- [19] P. Milde, D. Köhler, J. Seidel, L. M. Eng, A. Bauer, A. Chacon, J. Kindervater, S. Mühlbauer, C. Pfleiderer, S. Buhrandt, C. Schütte, and A. Rosch, [Science](http://dx.doi.org/10.1126/science.1234657) [340](http://dx.doi.org/10.1126/science.1234657), [1076](http://dx.doi.org/10.1126/science.1234657) [\(2013\)](http://dx.doi.org/10.1126/science.1234657).
- [20] A. Neubauer, C. Pfleiderer, B. Binz, A. Rosch, R. Ritz, P. G. Niklowitz, and P. Boni, *[Phys. Rev. Lett.](http://dx.doi.org/10.1103/PhysRevLett.102.186602)* **[102](http://dx.doi.org/10.1103/PhysRevLett.102.186602)**, [186602](http://dx.doi.org/10.1103/PhysRevLett.102.186602) [\(2009\)](http://dx.doi.org/10.1103/PhysRevLett.102.186602).
- [21] T. Adams, S. Mühlbauer, C. Pfleiderer, F. Jonietz, A. Bauer, A. Neubauer, R. Georgii, P. Böni, U. Keiderling, K. Everschor, M. Garst, and A. Rosch, [Phys. Rev. Lett.](http://dx.doi.org/10.1103/PhysRevLett.107.217206) **[107](http://dx.doi.org/10.1103/PhysRevLett.107.217206)**, [217206](http://dx.doi.org/10.1103/PhysRevLett.107.217206) [\(2011\)](http://dx.doi.org/10.1103/PhysRevLett.107.217206).
- [22] F. Jonietz, S. Mühlbauer, C. Pfleiderer, A. Neubauer, W. Münzer, A. Bauer, T. Adams, R. Georgii, P. Böni, R. A. Duine, K. Everschor, M. Garst, and A. Rosch, [Science](http://dx.doi.org/10.1126/science.1195709) **[330](http://dx.doi.org/10.1126/science.1195709)**, [1648](http://dx.doi.org/10.1126/science.1195709) [\(2010\)](http://dx.doi.org/10.1126/science.1195709).
- [23] T. Schulz, R. Ritz, A. Bauer, M. Halder, M. Wagner, C. Franz, C. Pfleiderer, K. Everschor, M. Garst, and A. Rosch, [Nat. Phys.](http://dx.doi.org/10.1038/nphys2231) **[8](http://dx.doi.org/10.1038/nphys2231)**, [301](http://dx.doi.org/10.1038/nphys2231) [\(2012\)](http://dx.doi.org/10.1038/nphys2231).
- [24] X. Z. Yu, N. Kanazawa, W. Z. Zhang, T. Nagai, T. Hara, K. Kimoto, Y. Matsui, and Y. O. Y. Tokura, [Nat. Commun.](http://dx.doi.org/10.1038/ncomms1990) **[3](http://dx.doi.org/10.1038/ncomms1990)**, [988](http://dx.doi.org/10.1038/ncomms1990) [\(2012\)](http://dx.doi.org/10.1038/ncomms1990).
- [25] R. Ritz, M. Halder, C. Franz, A. Bauer, M. Wagner, R. Bamler, A. Rosch, and C. Pfleiderer, [Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.87.134424) **[87](http://dx.doi.org/10.1103/PhysRevB.87.134424)**, [134424](http://dx.doi.org/10.1103/PhysRevB.87.134424) [\(2013\)](http://dx.doi.org/10.1103/PhysRevB.87.134424).
- [26] R. Ritz, M. Halder, M. Wagner, C. Franz, A. Bauer, and C. Pfleiderer, [Nature \(London\)](http://dx.doi.org/10.1038/nature12023) **[497](http://dx.doi.org/10.1038/nature12023)**, [231](http://dx.doi.org/10.1038/nature12023) [\(2013\)](http://dx.doi.org/10.1038/nature12023).
- [27] N. Manyala, Y. Sidis, J. F. DiTusa, G. Aeppli, D. P. Young, and Z. Fisk, [Nat. Mater.](http://dx.doi.org/10.1038/nmat1103) **[3](http://dx.doi.org/10.1038/nmat1103)**, [255](http://dx.doi.org/10.1038/nmat1103) [\(2004\)](http://dx.doi.org/10.1038/nmat1103).
- [28] A. Bauer, A. Neubauer, C. Franz, W. Münzer, M. Garst, and C. Pfleiderer, [Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.82.064404) **[82](http://dx.doi.org/10.1103/PhysRevB.82.064404)**, [064404](http://dx.doi.org/10.1103/PhysRevB.82.064404) [\(2010\)](http://dx.doi.org/10.1103/PhysRevB.82.064404).
- [29] S. Kusaka, K. Yamamoto, T. Komatsubara, and Y. Ishikawa, [Solid State Commun.](http://dx.doi.org/10.1016/0038-1098(76)91307-7) **[20](http://dx.doi.org/10.1016/0038-1098(76)91307-7)**, [925](http://dx.doi.org/10.1016/0038-1098(76)91307-7) [\(1976\)](http://dx.doi.org/10.1016/0038-1098(76)91307-7).
- [30] A. E. Petrova and S. M. Stishov, [J. Phys.: Condens. Matter](http://dx.doi.org/10.1088/0953-8984/21/19/196001) **[21](http://dx.doi.org/10.1088/0953-8984/21/19/196001)**, [196001](http://dx.doi.org/10.1088/0953-8984/21/19/196001) [\(2009\)](http://dx.doi.org/10.1088/0953-8984/21/19/196001).
- [31] E. Fawcett, J. Maita, and J. Wernick, lntern. J. Magnetism **1**, 29 (1970).
- [32] M. Matsunaga, Y. Ishikawa, and T. Nakajima, [J. Phys. Soc. Jpn.](http://dx.doi.org/10.1143/JPSJ.51.1153) **[51](http://dx.doi.org/10.1143/JPSJ.51.1153)**, [1153](http://dx.doi.org/10.1143/JPSJ.51.1153) [\(1982\)](http://dx.doi.org/10.1143/JPSJ.51.1153).
- [33] S. M. Stishov, A. E. Petrova, S. Khasanov, G. K. Panova, A. [A. Shikov, J. C. Lashley, D. Wu, and T. A. Lograsso,](http://dx.doi.org/10.1088/0953-8984/20/23/235222) J. Phys.: Condens. Matter **[20](http://dx.doi.org/10.1088/0953-8984/20/23/235222)**, [235222](http://dx.doi.org/10.1088/0953-8984/20/23/235222) [\(2008\)](http://dx.doi.org/10.1088/0953-8984/20/23/235222).
- [34] P. Nyhus, S. L. Cooper, and Z. Fisk, [Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.51.15626) **[51](http://dx.doi.org/10.1103/PhysRevB.51.15626)**, [15626](http://dx.doi.org/10.1103/PhysRevB.51.15626) [\(1995\)](http://dx.doi.org/10.1103/PhysRevB.51.15626).
- [35] A.-M. Racu, D. Menzel, J. Schoenes, and K. Doll, *[Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.76.115103)* **[76](http://dx.doi.org/10.1103/PhysRevB.76.115103)**, [115103](http://dx.doi.org/10.1103/PhysRevB.76.115103) [\(2007\)](http://dx.doi.org/10.1103/PhysRevB.76.115103).
- [36] T. P. Devereaux, D. Einzel, B. Stadlober, R. Hackl, D. H. Leach, and J. J. Neumeier, [Phys. Rev. Lett.](http://dx.doi.org/10.1103/PhysRevLett.72.396) **[72](http://dx.doi.org/10.1103/PhysRevLett.72.396)**, [396](http://dx.doi.org/10.1103/PhysRevLett.72.396) [\(1994\)](http://dx.doi.org/10.1103/PhysRevLett.72.396).
- [37] T. P. Devereaux and R. Hackl, [Rev. Mod. Phys.](http://dx.doi.org/10.1103/RevModPhys.79.175) **[79](http://dx.doi.org/10.1103/RevModPhys.79.175)**, [175](http://dx.doi.org/10.1103/RevModPhys.79.175) [\(2007\)](http://dx.doi.org/10.1103/RevModPhys.79.175).
- [38] [S. Caprara, C. Di Castro, M. Grilli, and D. Suppa,](http://dx.doi.org/10.1103/PhysRevLett.95.117004) *Phys. Rev.* Lett. **[95](http://dx.doi.org/10.1103/PhysRevLett.95.117004)**, [117004](http://dx.doi.org/10.1103/PhysRevLett.95.117004) [\(2005\)](http://dx.doi.org/10.1103/PhysRevLett.95.117004).
- [39] S. Caprara, C. Di Castro, B. Muschler, W. Prestel, R. Hackl, M. Lambacher, A. Erb, S. Komiya, Y. Ando, and M. Grilli, [Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.84.054508) **[84](http://dx.doi.org/10.1103/PhysRevB.84.054508)**, [054508](http://dx.doi.org/10.1103/PhysRevB.84.054508) [\(2011\)](http://dx.doi.org/10.1103/PhysRevB.84.054508).
- [40] H.-M. Eiter, M. Lavagnini, R. Hackl, E. A. Nowadnick, A. F. Kemper, T. P. Devereaux, J.-H. Chu, J. G. Analytis, I. R. Fisher, and L. Degiorgi, [Proc. Natl. Acad. Sci. USA](http://dx.doi.org/10.1073/pnas.1214745110) **[110](http://dx.doi.org/10.1073/pnas.1214745110)**, [64](http://dx.doi.org/10.1073/pnas.1214745110) [\(2013\)](http://dx.doi.org/10.1073/pnas.1214745110).
- [41] [T. Tite, G. J. Shu, F. C. Chou, and Y.-M. Chang,](http://dx.doi.org/10.1063/1.3464980) Appl. Phys. Lett. **[97](http://dx.doi.org/10.1063/1.3464980)**, [031909](http://dx.doi.org/10.1063/1.3464980) [\(2010\)](http://dx.doi.org/10.1063/1.3464980).
- [42] F. P. Mena, D. van der Marel, A. Damascelli, M. Fäth, A. A. Menovsky, and J. A. Mydosh, [Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.67.241101) **[67](http://dx.doi.org/10.1103/PhysRevB.67.241101)**, [241101](http://dx.doi.org/10.1103/PhysRevB.67.241101) [\(2003\)](http://dx.doi.org/10.1103/PhysRevB.67.241101).
- [43] D. Belitz, T. R. Kirkpatrick, and A. Rosch, [Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.74.024409) **[74](http://dx.doi.org/10.1103/PhysRevB.74.024409)**, [024409](http://dx.doi.org/10.1103/PhysRevB.74.024409) [\(2006\)](http://dx.doi.org/10.1103/PhysRevB.74.024409).
- [44] A. Neubauer, J. Bœuf, A. Bauer, B. Russ, H. v. Löhneysen, and C. Pfleiderer, [Rev. Sci. Instrum.](http://dx.doi.org/10.1063/1.3523056) **[82](http://dx.doi.org/10.1063/1.3523056)**, [013902](http://dx.doi.org/10.1063/1.3523056) [\(2011\)](http://dx.doi.org/10.1063/1.3523056).
- [45] W. Prestel, Ph.D. thesis, Technische Universität München, 2012.
- [46] [R. Hackl, R. Kaiser, and S. Schicktanz,](http://dx.doi.org/10.1088/0022-3719/16/9/016) J. Phys. C: Solid State Phys. **[16](http://dx.doi.org/10.1088/0022-3719/16/9/016)**, [1729](http://dx.doi.org/10.1088/0022-3719/16/9/016) [\(1983\)](http://dx.doi.org/10.1088/0022-3719/16/9/016).
- [47] R. Hackl, Ph.D. thesis, Technische Universität München, 1987.
- [48] W. Hayes and R. Loudon, *Scattering of Light by Crystals*(Wiley, New York, 1978).
- [49] M. Opel, R. Nemetschek, C. Hoffmann, R. Philipp, P. F. Müller, R. Hackl, I. Tüttő, A. Erb, B. Revaz, E. Walker, H. Berger, and L. Forró, *[Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.61.9752)* **[61](http://dx.doi.org/10.1103/PhysRevB.61.9752)**, [9752](http://dx.doi.org/10.1103/PhysRevB.61.9752) [\(2000\)](http://dx.doi.org/10.1103/PhysRevB.61.9752).
- [50] S. V. Demishev, V. V. Glushkov, I. I. Lobanova, M. A. Anisimov, V. Y. Ivanov, T. V. Ishchenko, M. S. Karasev, N. A. Samarin, N. E. Sluchanko, V. M. Zimin, and A. V. Semeno, [Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.85.045131) **[85](http://dx.doi.org/10.1103/PhysRevB.85.045131)**, [045131](http://dx.doi.org/10.1103/PhysRevB.85.045131) [\(2012\)](http://dx.doi.org/10.1103/PhysRevB.85.045131).
- [51] P. G. Klemens, [Phys. Rev.](http://dx.doi.org/10.1103/PhysRev.148.845) **[148](http://dx.doi.org/10.1103/PhysRev.148.845)**, [845](http://dx.doi.org/10.1103/PhysRev.148.845) [\(1966\)](http://dx.doi.org/10.1103/PhysRev.148.845).
- [52] J. Menéndez and M. Cardona, *[Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.29.2051)* [29](http://dx.doi.org/10.1103/PhysRevB.29.2051), [2051](http://dx.doi.org/10.1103/PhysRevB.29.2051) [\(1984\)](http://dx.doi.org/10.1103/PhysRevB.29.2051).
- [53] C. Postmus, J. R. Ferraro, and S. S. Mitra, [Phys. Rev.](http://dx.doi.org/10.1103/PhysRev.174.983) **[174](http://dx.doi.org/10.1103/PhysRev.174.983)**, [983](http://dx.doi.org/10.1103/PhysRev.174.983) [\(1968\)](http://dx.doi.org/10.1103/PhysRev.174.983).
- [54] W. Borer, S. Mitra, and K. Namjoshi, [Solid State Commun.](http://dx.doi.org/10.1016/0038-1098(71)90399-1) **[9](http://dx.doi.org/10.1016/0038-1098(71)90399-1)**, [1377](http://dx.doi.org/10.1016/0038-1098(71)90399-1) [\(1971\)](http://dx.doi.org/10.1016/0038-1098(71)90399-1).
- [55] R. A. Cowley, [J. Phys. \(Paris\)](http://dx.doi.org/10.1051/jphys:019650026011065900) **[26](http://dx.doi.org/10.1051/jphys:019650026011065900)**, [659](http://dx.doi.org/10.1051/jphys:019650026011065900) [\(1965\)](http://dx.doi.org/10.1051/jphys:019650026011065900).
- [56] [G. P. Zinoveva, L. P. Andreeva, and P. V. Geld,](http://dx.doi.org/10.1002/pssa.2210230244) Phys. Status Solidi A **[23](http://dx.doi.org/10.1002/pssa.2210230244)**, [711](http://dx.doi.org/10.1002/pssa.2210230244) [\(1974\)](http://dx.doi.org/10.1002/pssa.2210230244).
- [57] [J. R. Jasperse, A. Kahan, J. N. Plendl, and S. S. Mitra,](http://dx.doi.org/10.1103/PhysRev.146.526) *Phys.* Rev. **[146](http://dx.doi.org/10.1103/PhysRev.146.526)**, [526](http://dx.doi.org/10.1103/PhysRev.146.526) [\(1966\)](http://dx.doi.org/10.1103/PhysRev.146.526).
- [58] N. W. Ashcroft and N. D. Mermin, *Solid State Physics*(Saunders College, Philadelphia, 1988).
- [59] T. Barron, J. Collins, and G. White, [Adv. Phys.](http://dx.doi.org/10.1080/00018738000101426) **[29](http://dx.doi.org/10.1080/00018738000101426)**, [609](http://dx.doi.org/10.1080/00018738000101426) [\(1980\)](http://dx.doi.org/10.1080/00018738000101426).
- [60] [G. K. White, R. B. Roberts, and E. Fawcett,](http://dx.doi.org/10.1088/0305-4608/16/4/009) J. Phys. F: Met. Phys. **[16](http://dx.doi.org/10.1088/0305-4608/16/4/009)**, [449](http://dx.doi.org/10.1088/0305-4608/16/4/009) [\(1986\)](http://dx.doi.org/10.1088/0305-4608/16/4/009).
- [61] L. Pauling and A. M. Soldate, [Acta Crystallogr.](http://dx.doi.org/10.1107/S0365110X48000570) **[1](http://dx.doi.org/10.1107/S0365110X48000570)**, [212](http://dx.doi.org/10.1107/S0365110X48000570) [\(1948\)](http://dx.doi.org/10.1107/S0365110X48000570).
- [62] D. J. Lockwood and M. G. Cottam, [J. Appl. Phys.](http://dx.doi.org/10.1063/1.342186) **[64](http://dx.doi.org/10.1063/1.342186)**, [5876](http://dx.doi.org/10.1063/1.342186) [\(1988\)](http://dx.doi.org/10.1063/1.342186).
- [63] X. K. Chen, J. C. Irwin, and J. P. Franck, [Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.52.R13130) **[52](http://dx.doi.org/10.1103/PhysRevB.52.R13130)**, [R13130](http://dx.doi.org/10.1103/PhysRevB.52.R13130) [\(1995\)](http://dx.doi.org/10.1103/PhysRevB.52.R13130).
- [64] J. Laverdière, S. Jandl, A. A. Mukhin, V. Y. Ivanov, V. G. Ivanov, and M. N. Iliev, [Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.73.214301) **[73](http://dx.doi.org/10.1103/PhysRevB.73.214301)**, [214301](http://dx.doi.org/10.1103/PhysRevB.73.214301) [\(2006\)](http://dx.doi.org/10.1103/PhysRevB.73.214301).
- [65] C. Pfleiderer, [J. Low Temp. Phys.](http://dx.doi.org/10.1007/s10909-007-9307-z) **[147](http://dx.doi.org/10.1007/s10909-007-9307-z)**, [231](http://dx.doi.org/10.1007/s10909-007-9307-z) [\(2007\)](http://dx.doi.org/10.1007/s10909-007-9307-z).
- [66] E. Fawcett, [Phys. B \(Amsterdam\)](http://dx.doi.org/10.1016/0921-4526(89)90109-9) **[161](http://dx.doi.org/10.1016/0921-4526(89)90109-9)**, [83](http://dx.doi.org/10.1016/0921-4526(89)90109-9) [\(1989\)](http://dx.doi.org/10.1016/0921-4526(89)90109-9).
- [67] J. W. Allen and J. C. Mikkelsen, [Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.15.2952) **[15](http://dx.doi.org/10.1103/PhysRevB.15.2952)**, [2952](http://dx.doi.org/10.1103/PhysRevB.15.2952) [\(1977\)](http://dx.doi.org/10.1103/PhysRevB.15.2952).
- [68] D. Tanner and T. Timusk, in *Physical Properties of High Temperature Superconductors III*, edited by D. Ginsberg (World Scientific, Singapore, 1992), p. 363.
- [[6](http://dx.doi.org/10.1103/PhysRevB.6.1226)9] W. Götze and P. Wölfle, *[Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.6.1226)* **6**, [1226](http://dx.doi.org/10.1103/PhysRevB.6.1226) [\(1972\)](http://dx.doi.org/10.1103/PhysRevB.6.1226).
- [70] B. Muschler, W. Prestel, R. Hackl, T. P. Devereaux, J. G. Analytis, J.-H. Chu, and I. R. Fisher, [Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.80.180510) **[80](http://dx.doi.org/10.1103/PhysRevB.80.180510)**, [180510](http://dx.doi.org/10.1103/PhysRevB.80.180510) [\(2009\)](http://dx.doi.org/10.1103/PhysRevB.80.180510).
- [71] I. I. Mazin, T. P. Devereaux, J. G. Analytis, J.-H. Chu, I. R. Fisher, B. Muschler, and R. Hackl, [Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.82.180502) **[82](http://dx.doi.org/10.1103/PhysRevB.82.180502)**, [180502](http://dx.doi.org/10.1103/PhysRevB.82.180502) [\(2010\)](http://dx.doi.org/10.1103/PhysRevB.82.180502).
- [72] T. Jeong and W. E. Pickett, [Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.70.075114) **[70](http://dx.doi.org/10.1103/PhysRevB.70.075114)**, [075114](http://dx.doi.org/10.1103/PhysRevB.70.075114) [\(2004\)](http://dx.doi.org/10.1103/PhysRevB.70.075114).
- [73] P. B. Allen, [Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.13.1416) **[13](http://dx.doi.org/10.1103/PhysRevB.13.1416)**, [1416](http://dx.doi.org/10.1103/PhysRevB.13.1416) [\(1976\)](http://dx.doi.org/10.1103/PhysRevB.13.1416).
- [74] N. Toyota, M. Lang, and J. Müller, *Low-Dimensional Molecular Metals* (Springer, Berlin, 2007).
- [75] F. Venturini, Q.-M. Zhang, R. Hackl, A. Lucarelli, S. Lupi, [M. Ortolani, P. Calvani, N. Kikugawa, and T. Fujita,](http://dx.doi.org/10.1103/PhysRevB.66.060502) Phys. Rev. B **[66](http://dx.doi.org/10.1103/PhysRevB.66.060502)**, [060502](http://dx.doi.org/10.1103/PhysRevB.66.060502) [\(2002\)](http://dx.doi.org/10.1103/PhysRevB.66.060502).
- [76] A. Chattopadhyay and M. Jarrell, [Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.56.R2920) **[56](http://dx.doi.org/10.1103/PhysRevB.56.R2920)**, [R2920](http://dx.doi.org/10.1103/PhysRevB.56.R2920) [\(1997\)](http://dx.doi.org/10.1103/PhysRevB.56.R2920).
- [77] F. Venturini, M. Opel, T. P. Devereaux, J. K. Freericks, I. Tüttő, B. Revaz, E. Walker, H. Berger, L. Forró, and R. Hackl, *Phys.* Rev. Lett. **[89](http://dx.doi.org/10.1103/PhysRevLett.89.107003)**, [107003](http://dx.doi.org/10.1103/PhysRevLett.89.107003) [\(2002\)](http://dx.doi.org/10.1103/PhysRevLett.89.107003).
- [78] N. Hussey, K. Takenaka, and H. Takagi, [Philos. Mag.](http://dx.doi.org/10.1080/14786430410001716944) **[84](http://dx.doi.org/10.1080/14786430410001716944)**, [2847](http://dx.doi.org/10.1080/14786430410001716944) [\(2004\)](http://dx.doi.org/10.1080/14786430410001716944).
- [79] N. E. Hussey, J. C. Alexander, and R. A. Cooper, *[Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.74.214508)* **[74](http://dx.doi.org/10.1103/PhysRevB.74.214508)**, [214508](http://dx.doi.org/10.1103/PhysRevB.74.214508) [\(2006\)](http://dx.doi.org/10.1103/PhysRevB.74.214508).
- [80] A. Neubauer (private communication).
- [81] A. Zawadowski and M. Cardona, [Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.42.10732) **[42](http://dx.doi.org/10.1103/PhysRevB.42.10732)**, [10732](http://dx.doi.org/10.1103/PhysRevB.42.10732) [\(1990\)](http://dx.doi.org/10.1103/PhysRevB.42.10732).
- [82] A. Bauer and C. Pfleiderer, [Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.85.214418) **[85](http://dx.doi.org/10.1103/PhysRevB.85.214418)**, [214418](http://dx.doi.org/10.1103/PhysRevB.85.214418) [\(2012\)](http://dx.doi.org/10.1103/PhysRevB.85.214418).
- [83] [F. Freimuth, R. Bamler, Y. Mokrousov, and A. Rosch,](http://dx.doi.org/10.1103/PhysRevB.88.214409) *Phys.* Rev. B **[88](http://dx.doi.org/10.1103/PhysRevB.88.214409)**, [214409](http://dx.doi.org/10.1103/PhysRevB.88.214409) [\(2013\)](http://dx.doi.org/10.1103/PhysRevB.88.214409).
- [84] C. Franz, F. Freimuth, A. Bauer, R. Ritz, C. Schnarr, C. Duvinage, T. Adams, S. Blügel, A. Rosch, Y. Mokrousov, and C. Pfleiderer, [Phys. Rev. Lett.](http://dx.doi.org/10.1103/PhysRevLett.112.186601) **[112](http://dx.doi.org/10.1103/PhysRevLett.112.186601)**, [186601](http://dx.doi.org/10.1103/PhysRevLett.112.186601) [\(2014\)](http://dx.doi.org/10.1103/PhysRevLett.112.186601).
- [85] J. Ready, *Effects of High Power Laser Radiation* (Academic Press, New York, 1971).
- [86] D. Einzel and R. Hackl, [J. Raman Spectrosc.](http://dx.doi.org/10.1002/(SICI)1097-4555(199603)27:3/4<307::AID-JRS966>3.0.CO;2-J) **[27](http://dx.doi.org/10.1002/(SICI)1097-4555(199603)27:3/4<307::AID-JRS966>3.0.CO;2-J)**, [307](http://dx.doi.org/10.1002/(SICI)1097-4555(199603)27:3/4<307::AID-JRS966>3.0.CO;2-J) [\(1996\)](http://dx.doi.org/10.1002/(SICI)1097-4555(199603)27:3/4<307::AID-JRS966>3.0.CO;2-J).
- [87] B. S. Shastry and B. I. Shraiman, [Phys. Rev. Lett.](http://dx.doi.org/10.1103/PhysRevLett.65.1068) **[65](http://dx.doi.org/10.1103/PhysRevLett.65.1068)**, [1068](http://dx.doi.org/10.1103/PhysRevLett.65.1068) [\(1990\)](http://dx.doi.org/10.1103/PhysRevLett.65.1068).
- [88] F. Michaud, F. Vernay, and F. Mila, [Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.84.184424) **[84](http://dx.doi.org/10.1103/PhysRevB.84.184424)**, [184424](http://dx.doi.org/10.1103/PhysRevB.84.184424) [\(2011\)](http://dx.doi.org/10.1103/PhysRevB.84.184424).
- [89] P. E. Sulewski, P. A. Fleury, K. B. Lyons, and S.-W. Cheong, [Phys. Rev. Lett.](http://dx.doi.org/10.1103/PhysRevLett.67.3864) **[67](http://dx.doi.org/10.1103/PhysRevLett.67.3864)**, [3864](http://dx.doi.org/10.1103/PhysRevLett.67.3864) [\(1991\)](http://dx.doi.org/10.1103/PhysRevLett.67.3864).